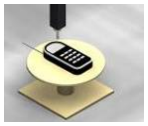
PCTEST ENGINEERING LABORATORY, INC.
7185 Oakland Mills Road, Columbia, MD 21046 USA
Tel. 410.290.6652 / Fax 410.290.6554
http://www.pctestlab.com



HEARING AID COMPATIBILITY

Applicant Name:
Panasonic Corporation of North America
Two Riverfront Plaza, 9th Floor
Newark, NJ 07102
United States

Date of Testing:
January 6-10, 2014
Test Site/Location:
PCTEST Lab, Columbia, MD, USA
Test Report Serial No.:
0Y1402260519-R2.ACJ

FCC ID: **ACJEB3910A**

APPLICANT: **PANASONIC CORPORATION OF NORTH AMERICA**

Scope of Test:	RF Emissions Testing
Application Type:	Engineering Evaluation (For reference only)
HAC Standard:	ANSI C63.19-2011
EUT Type:	Portable Handset
Model(s):	FZ-X1
Test Device Serial No.:	*Pre-Production Sample* [S/N: #049]

C63.19-2011 HAC Category: **M3 (RF EMISSIONS CATEGORY)**

This revised Test Report (S/N: 0Y1402260519-R2.ACJ) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category for performance evaluation purposes only, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

Randy Ortanez
President

Note: Testing was performed in accordance to ISO/IEC 17025:2005 guidelines and requirements.

TABLE OF CONTENTS

1. INTRODUCTION 3
2. TEST SITE LOCATION 4
3. EUT DESCRIPTION 5
4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES 6
5. SYSTEM SPECIFICATIONS 7
6. TEST PROCEDURE 12
7. SYSTEM CHECK 14
8. MODULATION INTERFERENCE FACTOR 17
9. RF CONDUCTED POWER MEASUREMENTS 21
10. JUSTIFICATION OF HELD TO EAR MODES TESTED 28
11. OVERALL MEASUREMENT SUMMARY 29
12. EQUIPMENT LIST 32
13. MEASUREMENT UNCERTAINTY 33
14. TEST DATA 34
15. CALIBRATION CERTIFICATES 45
16. CONCLUSION 73
17. REFERENCES 74
18. TEST PHOTOGRAPHS 76

1. INTRODUCTION

ANSI Standard C63.19-2011 gives guidance for performing Hearing Aid Compatibility (HAC) testing on any wireless device using any communication protocol. This allows for the benefits of a wider array of devices to be available to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.

Figure 1-1 Hearing Aid *in-vitu*

2. TEST SITE LOCATION

2.1 INTRODUCTION

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the Baltimore-Washington International (BWI) airport, the city of Baltimore, and Washington, DC (See Figure 2-1).

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in the Stonewood Business Center, Guilford Industrial Park, Columbia, Maryland. The site address is 7185 Oakland Mills Road, Columbia, MD 21046. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 10' 24" N latitude and 76° 49' 50" W longitude.

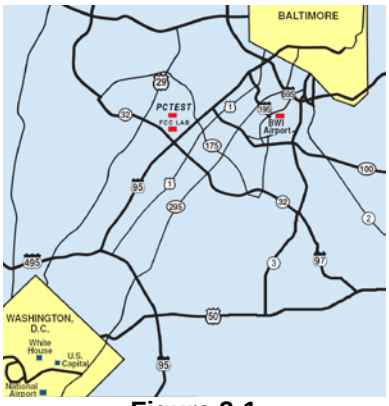


Figure 2-1
Map of the Greater Baltimore and Metropolitan Washington, D.C. area

2.2 Test Facility / Accreditations:

Measurements were performed at an independent accredited PCTEST Engineering Lab located in Columbia, MD, U.S.A.

- PCTEST Lab is accredited to ISO 17025-2005 by the American Association for Laboratory Accreditation (A2LA) in Specific Absorption Rate (SAR) testing, Hearing-Aid Compatibility (HAC), Long-Term Evolution (LTE), CTIA Test Plans, and wireless testing for FCC and Industry Canada Rules.
- PCTEST Lab is accredited to ISO 17025 by U.S. National Institute of Standards and Technology (NIST) under the National Voluntary Laboratory Accreditation Program (NVLAP Lab code: 100431-0) in EMC, FCC and Telecommunications.
- PCTEST facility is an FCC registered (PCTEST Reg. No. 90864) test facility with the site description report on file and has met all the requirements specified in Section 2.948 of the FCC Rules and Industry Canada (IC-2451).
- PCTEST Lab is a recognized U.S. Conformity Assessment Body (CAB) in EMC and R&TTE (n.b. 0982) under the U.S.-EU Mutual Recognition Agreement (MRA).

- PCTEST TCB is a Telecommunication Certification Body (TCB) accredited to ISO/IEC Guide 65 by the American National Standards Institute (ANSI) in all scopes of FCC Rules and all Industry Canada Standards (RSS).
- PCTEST facility is an IC registered (IC-2451) test laboratory with the site description on file at Industry Canada.

3. EUT DESCRIPTION

FCC ID:	ACJEB3910A
Manufacturer:	Panasonic Corporation of North America Two Riverfront Plaza, 9th Floor Newark, NJ 07102 United States
Model(s):	FZ-X1
Serial Number:	#049
Antenna Configurations:	Internal Antenna
HAC Test Configurations:	EDGE 850; 1Tx slot, Channels: 128, 190, 251; BT Off; WLAN Off; LTE Off EDGE 1900; 1Tx slot; Channels: 512, 661, 810; BT Off; WLAN Off; LTE Off Cell. EvDO; Rev.A; Channels: 1013, 384, 777; BT Off; WLAN Off; LTE Off PCS EvDO; Rev.A; Channels: 25, 600, 1175; BT Off; WLAN Off; LTE Off UMTS V; Channels: 4132, 4183, 4233; BT Off; WLAN Off; LTE Off UMTS II; Channels: 9262, 9400, 9538; BT Off; WLAN Off; LTE Off LTE Band 17; Channel 23790; BT Off; WLAN Off LTE Band 13; Channel 23230; BT Off; WLAN Off LTE Band 4; Channel 20175; BT Off; WLAN Off 2.4GHz WLAN; Channel 6; BT Off; LTE Off 5GHz WLAN; Channels 149 & 157; BT Off; LTE Off
EUT Type:	Portable Handset

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction
GPRS/ EDGE	850	DT	No[2]	Yes: 2.4GHz WIFI or BT	N/A	N/A	No
	1900						
UMTS	850	DT	No2	Yes: 2.4GHz WIFI or BT	N/A	N/A	N/A
	1900						
	HSPA	DT	No	Yes: 2.4GHz WIFI or BT	Yes		
CDMA	835	DT	No	Yes: 2.4GHz WIFI or BT	N/A	N/A	N/A
	1900						
	EVDO	DT	No2	Yes: 2.4GHz WIFI or BT	Yes		
LTE	700	DT	No2	Yes: 2.4GHz WIFI or BT	Yes	N/A	N/A
	700						
	1700						
WIFI	2450	DT	No2	Yes: CDMA, GPRS/EDGE, UMTS or LTE	Yes	N/A	N/A
	5200			No			
	5300						
	5500						
	5800						
BT	2450	DT	No	Yes: CDMA, GPRS/EDGE, UMTS or LTE	N/A	N/A	N/A

Type Transport
DT = Digital Data - Not intended for CMRS Service

Notes:
1. Evaluated for MIF and low-power exemption.
2. This mode does not support CMRS voice operations. Hence was not tested according to any FCC policies, although it was evaluated per ANSI C63.19-2011.

Table 3-1: ACJEB3910A HAC Air Interfaces

4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters
Near field Category	**E-field emissions CW dB(V/m)**
f < 960 MHz	
M1	50 to 55
M2	45 to 50
M3	40 to 45
M4	< 40
f > 960 MHz	
M1	40 to 45
M2	35 to 40
M3	30 to 35
M4	< 30

Table 4-1
WD near-field categories as defined in ANSI C63.19-2011

5. SYSTEM SPECIFICATIONS

ER3DV6 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges
Calibration:	In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%, k=2)
Frequency:	100 MHz to > 6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m (M3 or better device readings fall well below diode compression point)
Linearity:	± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm

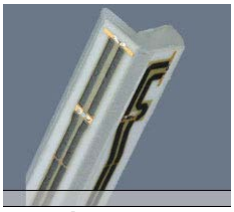
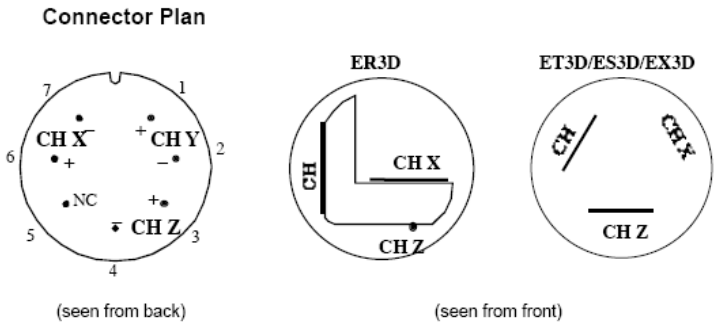


Figure 5-1
E-field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.



The antistatic shielding inside the probe is connected to the probe connector case.

Instrumentation Chain

Equation 1

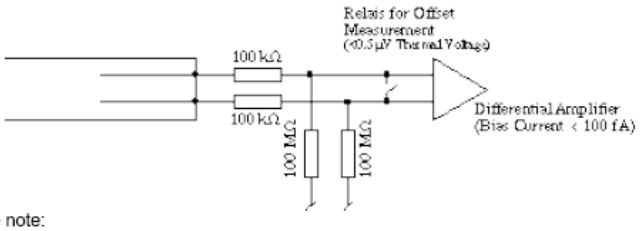
Conversion of Connector Voltage u_i to E-Field E_i

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

E_i:	electric field in V/m
u_i:	voltage of channel i at the connector in μV
$Norm_i$:	sensitivity of channel i in μV/(V/m)^2
$ConvF$:	enhancement factor in liquid (ConvF=1 for Air)
DCP:	diode compression point in μV
CF:	signal crest factor (peak power/average power)

Conditions of Calibration



Please note:
- a lower input impedance of the amplifier will result in different sensitivity factors $Norm_i$ and DCP
- larger bias currents will cause higher offset

Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

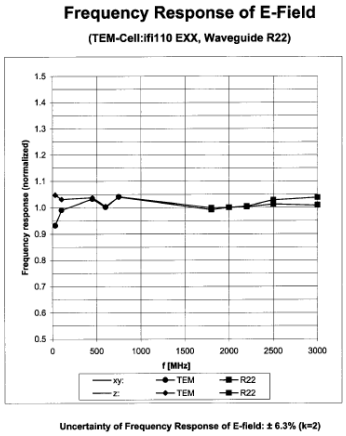


Figure 5-2 E-Field Probe Frequency Response

SPEAG Robotic System

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).

Figure 5-3
SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

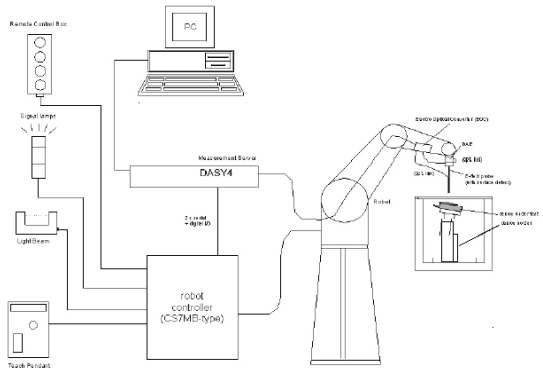


Figure 5-4
SPEAG Robotic System Diagram

DASY5 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with	V_i	= compensated signal of channel i	(i = x, y, z)
	U_i	= input signal of channel i	(i = x, y, z)
	cf	= crest factor of exciting field	(DASY parameter)
	dcp_i	= diode compression point	(DASY parameter)

From the compensated input signals the primary field data for each channel can be evaluated:

$$\text{E} - \text{fieldprobes}: \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with V_i = compensated signal of channel i (i = x, y, z)
$Norm_i$ = sensor sensitivity of channel i (i = x, y, z)
$\mu\text{V}/(\text{V/m})^2$ for E-field Probes
$ConvF$ = sensitivity enhancement in solution
E_i = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

6. TEST PROCEDURE

I. RF EMISSIONS

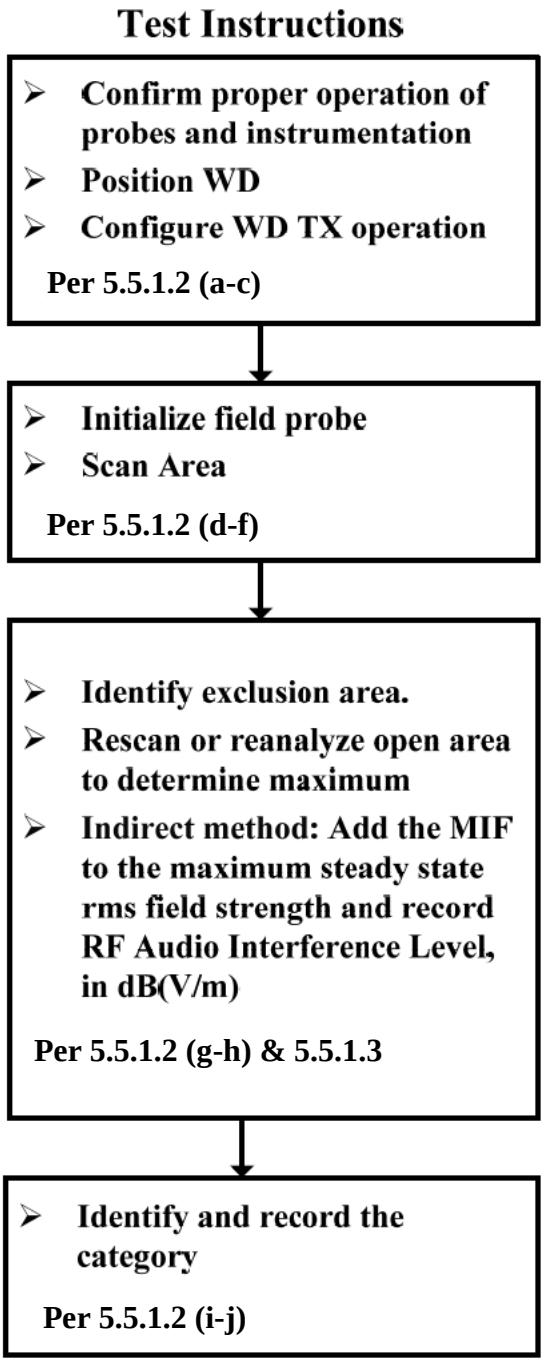


Figure 6-1 RF Emissions Flow Chart

Test Setup

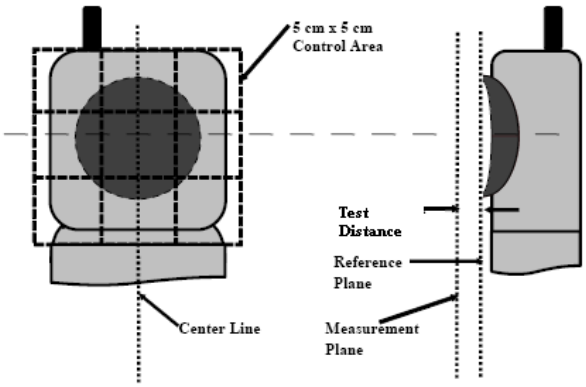


Figure 6-2
E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

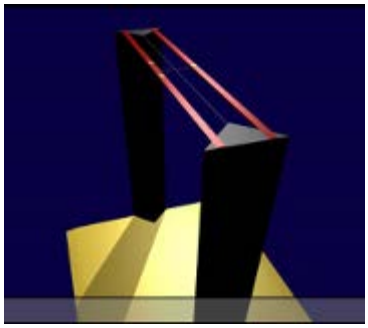


Figure 6-3
HAC Phantom

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.

2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.

3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.

4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.

5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.

6. The measurement system measured the field strength at the reference location.

7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360^{o} rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.

8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

7. SYSTEM CHECK

I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:

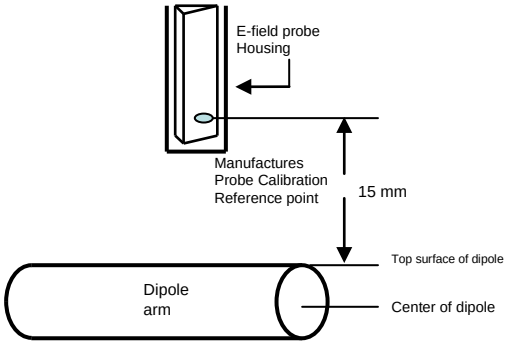


Figure 7-1
Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

RF power was recorded using both an average and a peak power reading meter.

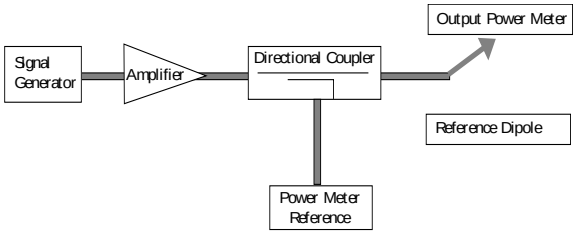


Figure 7-2
Setup for Desired Output Power to Dipole

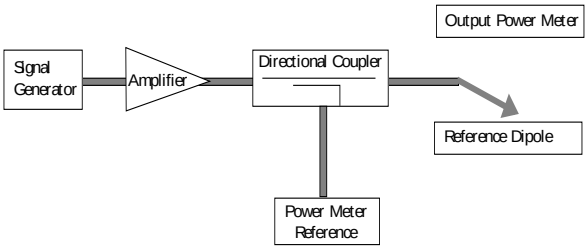


Figure 7-3
Setup to Dipole

Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:

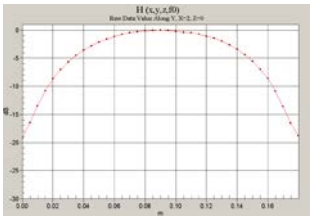


Figure 7-4
2-D Raw Data from scan along dipole axis

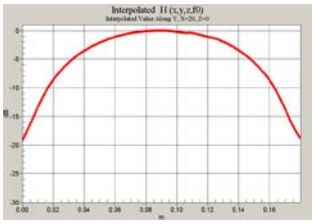


Figure 7-5
2-D Interpolated points from scan along dipole axis

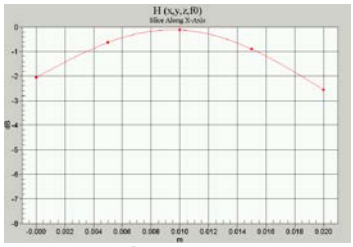


Figure 7-6
2-D Raw Data from scan along transverse axis

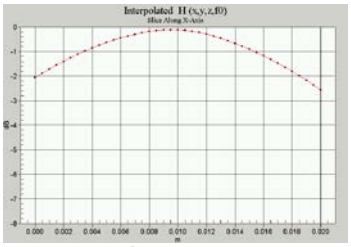


Figure 7-7
2-D Interpolated points from scan along transverse axis

III. System Check Results

Validation Results

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
835	1003	20.0	100.1	**107.7**	**-7.1%**
1880	1137	20.0	91.9	**90.2**	**1.8%**

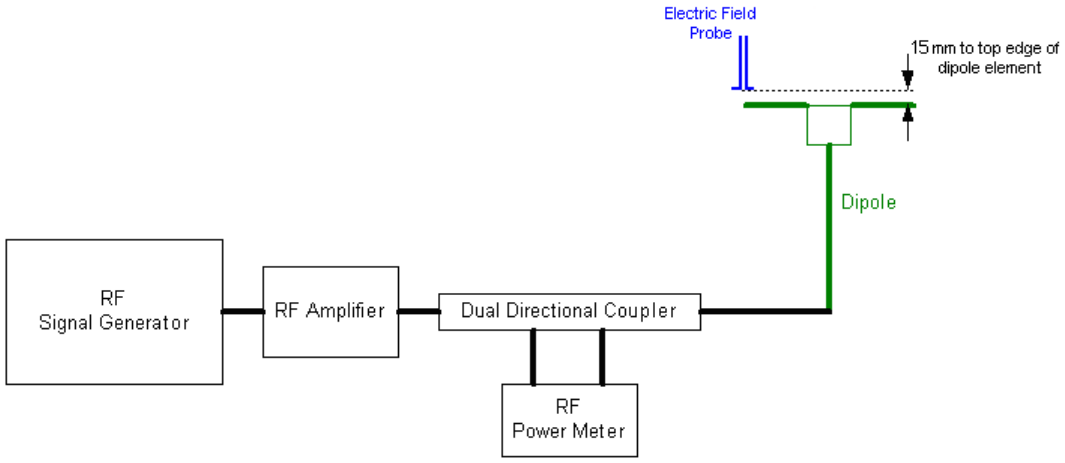


Figure 7-8
System Check Setup

8. MODULATION INTERFERENCE FACTOR

I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
b. Measure the steady-state RMS level at the output of the fast probe or sensor.
c. Measure the steady-state average level at the weighting output.
d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Series No: 10xx:

1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
2. The device was then set to continuously transmit at maximum power.
3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
5. Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

Audio Interference Level [dB(V/m)] = 20 * log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The transmit modes for this device have been investigated in this section of the report.

II. MIF Measurement Block Diagrams

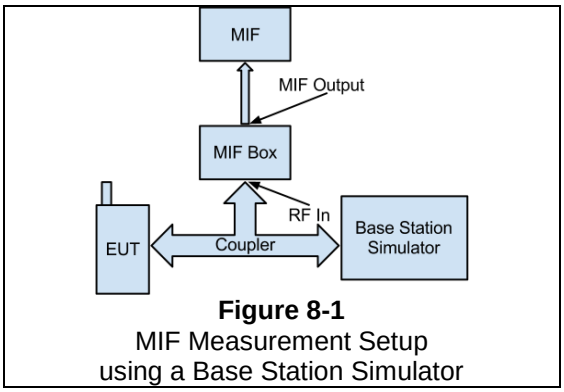


Figure 8-1
MIF Measurement Setup
using a Base Station Simulator

III. Measured Modulation Interference Factors:

Band	Channel	Rule Part	Frequency [MHz]	Measured MIF Values [dB]
				EvDO
				Rev.A
Cellular	1013	22H	824.7	-18.37
	384	22H	836.52	-18.44
	777	22H	848.31	-18.36
PCS	25	24E	1851.25	-18.69
	600	24E	1880	-19.26
	1175	24E	1908.75	-18.33

Table 8-1
EvDO Modulation Interference Factors[1]

Band	Channel	EDGE [dB] (1Tx Slot)
EDGE 850	128	4.90
	190	4.90
	251	4.32
EDGE 1900	512	4.45
	661	4.21
	810	4.29

Table 8-2
EDGE Modulation Interference Factors[1]

[1] Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

Mode	UMTS V [dB]			UMTS II [dB]		
	4132	4183	4233	9262	9400	9538
12.2 kbps RMC	-25.19	-26.04	-25.93	-27.33	-27.72	-24.86

Table 8-3
UMTS Modulation Interference Factors[1]

Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
4	1732.5	20175	10	16QAM	1	0	-9.81
4	1732.5	20175	10	QPSK	1	0	-14.73
4	1732.5	20175	10	16QAM	1	25	-9.60
4	1732.5	20175	10	16QAM	1	49	-9.69
4	1732.5	20175	10	16QAM	25	0	-16.07
4	1732.5	20175	10	16QAM	50	0	-16.25
4	1732.5	20175	5	16QAM	1	0	-10.13
4	1715	20000	10	16QAM	1	0	-9.64
4	1750	20350	10	16QAM	1	0	-9.94
13	782	23230	10	16QAM	1	25	-9.83[2]
17	710	23790	10	16QAM	1	25	-9.80[2]

Table 8-4
LTE Modulation Interference Factors[1,2,3]

Mode	802.11b (2.4 GHz) MIF [dB]			
	Data Rate [Mbps]			
	1	2	5.5	11
802.11b	-17.86	-17.15	-12.67	-12.63

Table 8-5
802.11b Modulation Interference Factors[1,2]

Mode	802.11g (2.4 GHz) MIF [dB]							
	Data Rate [Mbps]							
	6	9	12	18	24	36	48	54
802.11g	-17.61	-17.04	-14.90	-14.31	-14.12	-14.58	-15.24	-15.50

Table 8-6
802.11g Modulation Interference Factors[1,2]

[1] Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

[2] Note: LTE and WLAN MIF values were found to be independent of the transmit channel.

[3] Note: All LTE bands were found to have substantially similar MIF values given similar RB and BW configurations.

Mode	802.11n (2.4 GHz) MIF [dB]							
	Data Rate [Mbps]							
	6.5	13	20	26	39	52	58	65
802.11n	-17.11	-16.86	-14.68	-14.13	-13.85	-14.57	-15.19	-15.47

Table 8-7
802.11n (2.4GHz) Modulation Interference Factors[1,2]

Mode	802.11n (2.4 GHz) MIF [dB]							
	Data Rate [Mbps]							
	6.5	13	20	26	39	52	58	65
802.11n	-17.11	-16.86	-14.68	-14.13	-13.85	-14.57	-15.19	-15.47

Table 8-8
802.11n (2.4GHz) Modulation Interference Factors[1,2]

Mode	802.11a (5GHz) MIF [dB]							
	Data Rate [Mbps]							
	6	9	12	18	24	36	48	54
802.11a	-17.66	-16.67	-16.91	-16.24	-15.51	-14.96	-14.47	-14.43

Table 8-9
802.11a Modulation Interference Factors[1,2]

Mode	20MHz BW 802.11n (5GHz) MIF [dB]							
	Data Rate [Mbps]							
	6.5	13	20	26	39	52	58	65
802.11n	-17.35	-16.43	-16.58	-15.98	-15.23	-14.90	-14.44	-14.38

Table 8-10
802.11n (5GHz, 20MHz BW) Modulation Interference Factors[1,2]

Mode	40MHz BW 802.11n (5GHz) MIF [dB]							
	Data Rate [Mbps]							
	13.5	**27**	**40.5**	**54**	**81**	**108**	**121.5**	**135**
802.11n	-17.25	-20.42	-17.96	-18.73	-21.62	-19.45	-20.33	-20.02

Table 8-11
802.11n (5GHz, 40MHz BW) Modulation Interference Factors[1,2]

Mode	**80MHz BW 802.11ac (5GHz) MIF [dB]**									
	Data Rate [Mbps]									
	29.3	**58.5**	**87.8**	**117**	**175.5**	**234**	**263.3**	**292.5**	**351**	**390**
802.11ac	-17.52	-20.68	-18.23	-19.14	-21.81	-19.84	-20.62	-20.53	-21.82	-20.87

Table 8-12
802.11ac (80MHz BW) Modulation Interference Factors[1,2]

[1] Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

[2] Note: LTE and WLAN MIF values were found to be independent of the transmit channel.

9. RF CONDUCTED POWER MEASUREMENTS

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator.

II. HAC Measurement Conditions

Output Power Verification

Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces. See Table 9-1 for air interface specific settings of transmit power parameters.

Air Interface:	Parameter Name:	Parameter Set To:
EvDO	Power Control Bits	"All Up"
GPRS/EDGE	PCL	GSM850: "5" GSM1900: "0"
UMTS	TPC	"All 1's"
LTE	TPC	"Max Power"

Table 9-1
Power Control Parameters and Settings by Air Interface

III. Setup Used to Measure RF Conducted Powers

Power measurements were performed using a base station simulator under digital average power.

Figure 9-1
Power Measurement Setup

IV. CDMA Conducted Powers

Band	Channel	Rule Part	Frequency	TDSO SO32 [dBm]	TDSO SO32 [dBm]	1x EvDO Rev. 0 [dBm]	1x EvDO Rev. A [dBm]
	F-RC		MHz	FCH+SCH	FCH	(RTAP)	(RETAP)
Cellular	1013	22H	824.7	24.31	24.37	24.32	24.29
	384	22H	836.52	24.21	24.22	24.26	24.21
	777	22H	848.31	24.26	24.24	24.19	24.14
PCS	25	24E	1851.25	23.68	23.64	23.61	23.55
	600	24E	1880	23.66	23.67	23.65	23.61
	1175	24E	1908.75	23.80	23.83	23.94	23.84

V. GPRS/EDGE Conducted Powers

Band	Channel	GPRS [dBm] 1 Tx Slot	GPRS [dBm] 2 Tx Slot	GPRS [dBm] 3 Tx Slot	GPRS [dBm] 4 Tx Slot	EDGE [dBm] 1 Tx Slot	EDGE [dBm] 2 Tx Slot	EDGE [dBm] 3 Tx Slot	EDGE [dBm] 4 Tx Slot
GSM 850	128	32.38	30.25	28.99	**27.68**	27.03	24.44	22.50	21.23
	190	32.81	30.40	28.91	**27.70**	27.14	24.50	22.63	21.29
	251	32.78	30.60	28.93	**27.69**	27.07	24.48	22.60	21.26
GSM 1900	512	30.25	27.71	26.08	**24.75**	26.05	23.44	22.28	21.18
	661	30.11	27.56	25.97	**24.56**	26.08	23.37	22.14	20.92
	810	29.97	27.52	25.92	**24.63**	26.12	23.58	22.06	21.04

VI. UMTS Conducted Powers

Mode	Cellular Band [dBm]			PCS Band [dBm]		
	4132	4183	4233	9262	9400	9538
12.2 kbps RMC	23.96	23.98	23.98	23.92	23.95	24.00

VII. LTE Conducted Powers

Table 9-2
LTE Band 17 (710MHz) Conducted Powers - 5 MHz Bandwidth

Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	Conducted Power [dBm]	Target MPR [dB]	MPR Allowed per 3GPP [dB]
710.0	23790	5	QPSK	1	0	23.02	0	0
710.0	23790	5	QPSK	1	12	23.01	0	0
710.0	23790	5	QPSK	1	24	22.97	0	0
710.0	23790	5	QPSK	12	0	21.87	1	0-1
710.0	23790	5	QPSK	12	6	21.95	1	0-1
710.0	23790	5	QPSK	12	13	21.90	1	0-1
710.0	23790	5	QPSK	25	0	21.81	1	0-1
710.0	23790	5	16-QAM	1	0	22.02	1	0-1
710.0	23790	5	16-QAM	1	12	22.04	1	0-1
710.0	23790	5	16-QAM	1	24	21.99	1	0-1
710.0	23790	5	16-QAM	12	0	20.95	2	0-2
710.0	23790	5	16-QAM	12	6	21.01	2	0-2
710.0	23790	5	16-QAM	12	13	21.02	2	0-2
710.0	23790	5	16-QAM	25	0	20.84	2	0-2

Table 9-3
LTE Band 17 (710MHz) Conducted Powers - 10 MHz Bandwidth

Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	Conducted Power [dBm]	Target MPR [dB]	MPR Allowed per 3GPP [dB]
710.0	23790	10	QPSK	1	0	22.79	0	0
710.0	23790	10	QPSK	1	25	**22.95**	0	0
710.0	23790	10	QPSK	1	49	22.91	0	0
710.0	23790	10	QPSK	25	0	21.72	1	0-1
710.0	23790	10	QPSK	25	12	21.78	1	0-1
710.0	23790	10	QPSK	25	25	**21.81**	1	0-1
710.0	23790	10	QPSK	50	0	21.58	1	0-1
710.0	23790	10	16QAM	1	0	21.91	1	0-1
710.0	23790	10	16QAM	1	25	22.04	1	0-1
710.0	23790	10	16QAM	1	49	22.03	1	0-1
710.0	23790	10	16QAM	25	0	20.69	2	0-2
710.0	23790	10	16QAM	25	12	20.79	2	0-2
710.0	23790	10	16QAM	25	25	20.83	2	0-2
710.0	23790	10	16QAM	50	0	20.56	2	0-2

Table 9-4
LTE Band 13 (782MHz) Conducted Powers - 10 MHz Bandwidth

Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	Conducted Power [dBm]	Target MPR [dB]	MPR Allowed per 3GPP [dB]
782.0	23230	10	QPSK	1	0	**23.13**	0	0
782.0	23230	10	QPSK	1	25	22.74	0	0
782.0	23230	10	QPSK	1	49	22.93	0	0
782.0	23230	10	QPSK	25	0	**21.92**	1	0-1
782.0	23230	10	QPSK	25	12	21.85	1	0-1
782.0	23230	10	QPSK	25	25	21.76	1	0-1
782.0	23230	10	QPSK	50	0	21.67	1	0-1
782.0	23230	10	16QAM	1	0	22.15	1	0-1
782.0	23230	10	16QAM	1	25	21.98	1	0-1
782.0	23230	10	16QAM	1	49	22.13	1	0-1
782.0	23230	10	16QAM	25	0	20.77	2	0-2
782.0	23230	10	16QAM	25	12	20.64	2	0-2
782.0	23230	10	16QAM	25	25	20.73	2	0-2
782.0	23230	10	16QAM	50	0	20.60	2	0-2

Table 9-5
LTE Band 4 (1730MHz) Conducted Powers - 5 MHz Bandwidth

Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	Conducted Power [dBm]	Target MPR [dB]	MPR Allowed per 3GPP [dB]
1712.5	19975	5	QPSK	1	0	23.06	0	0
1712.5	19975	5	QPSK	1	12	23.05	0	0
1712.5	19975	5	QPSK	1	24	22.95	0	0
1712.5	19975	5	QPSK	12	0	22.46	1	0-1
1712.5	19975	5	QPSK	12	6	22.47	1	0-1
1712.5	19975	5	QPSK	12	13	22.47	1	0-1
1712.5	19975	5	QPSK	25	0	22.34	1	0-1
1712.5	19975	5	16-QAM	1	0	22.04	1	0-1
1712.5	19975	5	16-QAM	1	12	22.08	1	0-1
1712.5	19975	5	16-QAM	1	24	21.97	1	0-1
1712.5	19975	5	16-QAM	12	0	21.45	2	0-2
1712.5	19975	5	16-QAM	12	6	21.49	2	0-2
1712.5	19975	5	16-QAM	12	13	21.44	2	0-2
1712.5	19975	5	16-QAM	25	0	21.25	2	0-2
1732.5	20175	5	QPSK	1	0	23.11	0	0
1732.5	20175	5	QPSK	1	12	23.03	0	0
1732.5	20175	5	QPSK	1	24	23.05	0	0
1732.5	20175	5	QPSK	12	0	22.40	1	0-1
1732.5	20175	5	QPSK	12	6	22.28	1	0-1
1732.5	20175	5	QPSK	12	13	22.31	1	0-1
1732.5	20175	5	QPSK	25	0	22.29	1	0-1
1732.5	20175	5	16-QAM	1	0	22.05	1	0-1
1732.5	20175	5	16-QAM	1	12	22.10	1	0-1
1732.5	20175	5	16-QAM	1	24	21.97	1	0-1
1732.5	20175	5	16-QAM	12	0	21.43	2	0-2
1732.5	20175	5	16-QAM	12	6	21.47	2	0-2
1732.5	20175	5	16-QAM	12	13	21.47	2	0-2
1732.5	20175	5	16-QAM	25	0	21.33	2	0-2
1752.5	20375	5	QPSK	1	0	23.01	0	0
1752.5	20375	5	QPSK	1	12	22.94	0	0
1752.5	20375	5	QPSK	1	24	23.15	0	0
1752.5	20375	5	QPSK	12	0	22.47	1	0-1
1752.5	20375	5	QPSK	12	6	22.36	1	0-1
1752.5	20375	5	QPSK	12	13	22.47	1	0-1
1752.5	20375	5	QPSK	25	0	22.32	1	0-1
1752.5	20375	5	16-QAM	1	0	21.99	1	0-1
1752.5	20375	5	16-QAM	1	12	22.06	1	0-1
1752.5	20375	5	16-QAM	1	24	22.11	1	0-1
1752.5	20375	5	16-QAM	12	0	21.50	2	0-2
1752.5	20375	5	16-QAM	12	6	21.49	2	0-2
1752.5	20375	5	16-QAM	12	13	21.50	2	0-2
1752.5	20375	5	16-QAM	25	0	21.36	2	0-2

Table 9-6
LTE Band 4 (1730MHz) Conducted Powers - 10 MHz Bandwidth

Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	Conducted Power [dBm]	Target MPR [dB]	MPR Allowed per 3GPP [dB]
1715	20000	10	QPSK	1	0	23.01	0	0
1715	20000	10	QPSK	1	25	22.98	0	0
1715	20000	10	QPSK	1	49	22.87	0	0
1715	20000	10	QPSK	25	0	**21.93**	1	0-1
1715	20000	10	QPSK	25	12	21.80	1	0-1
1715	20000	10	QPSK	25	25	21.79	1	0-1
1715	20000	10	QPSK	50	0	21.79	1	0-1
1715	20000	10	16QAM	1	0	22.03	1	0-1
1715	20000	10	16QAM	1	25	21.91	1	0-1
1715	20000	10	16QAM	1	49	21.94	1	0-1
1715	20000	10	16QAM	25	0	20.99	2	0-2
1715	20000	10	16QAM	25	12	20.90	2	0-2
1715	20000	10	16QAM	25	25	20.85	2	0-2
1715	20000	10	16QAM	50	0	20.82	2	0-2
1732.5	20175	10	QPSK	1	0	**23.07**	0	0
1732.5	20175	10	QPSK	1	25	22.99	0	0
1732.5	20175	10	QPSK	1	49	22.87	0	0
1732.5	20175	10	QPSK	25	0	21.88	1	0-1
1732.5	20175	10	QPSK	25	12	21.85	1	0-1
1732.5	20175	10	QPSK	25	25	21.78	1	0-1
1732.5	20175	10	QPSK	50	0	21.71	1	0-1
1732.5	20175	10	16QAM	1	0	22.11	1	0-1
1732.5	20175	10	16QAM	1	25	22.06	1	0-1
1732.5	20175	10	16QAM	1	49	21.89	1	0-1
1732.5	20175	10	16QAM	25	0	20.90	2	0-2
1732.5	20175	10	16QAM	25	12	20.78	2	0-2
1732.5	20175	10	16QAM	25	25	20.77	2	0-2
1732.5	20175	10	16QAM	50	0	20.72	2	0-2
1750	20350	10	QPSK	1	0	22.94	0	0
1750	20350	10	QPSK	1	25	22.84	0	0
1750	20350	10	QPSK	1	49	23.04	0	0
1750	20350	10	QPSK	25	0	21.63	1	0-1
1750	20350	10	QPSK	25	12	21.70	1	0-1
1750	20350	10	QPSK	25	25	21.67	1	0-1
1750	20350	10	QPSK	50	0	21.58	1	0-1
1750	20350	10	16QAM	1	0	21.95	1	0-1
1750	20350	10	16QAM	1	25	21.90	1	0-1
1750	20350	10	16QAM	1	49	22.02	1	0-1
1750	20350	10	16QAM	25	0	20.71	2	0-2
1750	20350	10	16QAM	25	12	20.75	2	0-2
1750	20350	10	16QAM	25	25	20.77	2	0-2
1750	20350	10	16QAM	50	0	20.66	2	0-2

VIII. WLAN Conducted Powers

Table 9-7
IEEE 802.11b Average RF Power

Mode	Freq	Channel	802.11b (2.4 GHz) Conducted Power [dBm]			
			Data Rate [Mbps]			
	[MHz]		1	2	5.5	11
802.11b	2412	1*	14.66	14.63	14.68	14.62
802.11b	2437	6*	14.74	14.72	14.75	14.76
802.11b	2462	11*	**14.75**	14.79	14.79	14.84

Table 9-8
IEEE 802.11g Average RF Power

Mode	Freq	Channel	802.11g (2.4 GHz) Conducted Power [dBm]							
			Data Rate [Mbps]							
	[MHz]		6	9	12	18	24	36	48	54
802.11g	2412	1	9.33	9.35	9.38	9.31	9.28	9.35	9.36	9.34
802.11g	2417	2	12.65	12.54	12.64	12.68	12.53	12.64	12.58	12.51
802.11g	2437	6	12.54	12.53	12.71	12.57	12.45	12.55	12.55	12.61
802.11g	2457	10	12.60	12.52	12.57	12.59	12.55	12.62	12.60	12.64
802.11g	2462	11	9.34	9.36	9.33	9.39	9.44	9.31	9.29	9.33

Table 9-9
IEEE 802.11n Average RF Power

Mode	Freq	Channel	802.11n (2.4 GHz) Conducted Power [dBm]							
			Data Rate [Mbps]							
	[MHz]		6.5	13	20	26	39	52	58	65
802.11n	2412	1	9.33	9.36	9.30	9.27	9.36	9.35	9.35	9.33
802.11n	2417	2	11.65	11.62	11.63	11.68	11.64	11.65	11.60	11.67
802.11n	2437	6	11.54	11.67	11.62	11.64	11.68	11.57	11.58	11.59
802.11n	2457	10	11.55	11.62	11.52	11.54	11.52	11.52	11.57	11.52
802.11n	2462	11	9.30	9.32	9.33	9.41	9.31	9.35	9.31	9.34

Table 9-10
IEEE 802.11a Average RF Power

Mode	Freq	Channel	802.11a (5GHz) Conducted Power [dBm]							
			Data Rate [Mbps]							
	[MHz]		6	9	12	18	24	36	48	54
802.11a	5180	36*	11.51	11.53	11.47	11.52	11.50	11.47	11.46	11.51
802.11a	5200	40	13.44	13.45	13.41	13.39	13.48	13.50	13.49	13.43
802.11a	5220	44	13.41	13.40	13.38	13.45	13.42	13.46	13.40	13.45
802.11a	5240	48*	**13.53**	13.51	13.48	13.52	13.57	13.48	13.46	13.44
802.11a	5260	52*	15.05	15.01	14.97	15.00	15.06	15.04	15.08	15.03
802.11a	5280	56	15.06	15.00	15.04	15.03	15.06	14.99	15.02	15.01
802.11a	5300	60	**15.11**	15.10	15.07	15.09	15.14	15.16	15.08	15.04
802.11a	5320	64*	13.75	13.70	13.68	13.70	13.71	13.78	13.69	13.71
802.11a	5500	100	13.87	13.90	13.88	13.85	13.86	13.89	13.94	13.90
802.11a	5520	104*	15.25	15.32	15.30	15.20	15.31	15.22	15.29	15.27
802.11a	5540	108	15.20	15.18	15.26	15.24	15.16	15.24	15.22	15.20
802.11a	5560	112	15.31	15.28	15.29	15.34	15.25	15.28	15.24	15.30
802.11a	5580	116*	15.20	15.31	15.32	15.25	15.22	15.16	15.22	15.15
802.11a	5600	120	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11a	5620	124	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11a	5640	128	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11a	5660	132	15.31	15.32	15.30	15.34	15.28	15.22	15.25	15.24
802.11a	5680	136*	**15.45**	15.34	15.36	15.40	15.32	15.41	15.38	15.33
802.11a	5700	140	14.02	14.02	14.05	13.97	14.00	13.99	14.04	14.03
802.11a	5745	149*	15.42	15.40	15.38	15.39	15.40	15.46	15.42	15.44
802.11a	5765	153	**15.44**	15.41	15.46	15.43	15.44	15.42	15.47	15.40
802.11a	5785	157*	15.36	15.41	15.40	15.36	15.34	15.36	15.24	15.32
802.11a	5805	161	15.33	15.36	15.37	15.32	15.34	15.35	15.36	15.30
802.11a	5825	165*	15.21	15.25	15.28	15.24	15.24	15.20	15.18	15.26

Table 9-11
IEEE 802.11n Average RF Power – 20MHz Bandwidth

Mode	Freq	Channel	20MHz BW 802.11n (5GHz) Conducted Power [dBm]							
			Data Rate [Mbps]							
	[MHz]		6.5	13	19.5	26	39	52	58.5	65
802.11n	5180	36	11.55	11.52	11.56	11.50	11.52	11.54	11.48	11.52
802.11n	5200	40	13.61	13.60	13.58	13.63	13.64	13.52	13.57	13.55
802.11n	5220	44	13.44	13.42	13.51	13.40	13.38	13.45	13.37	13.45
802.11n	5240	48	13.61	13.62	13.57	13.60	13.64	13.60	13.55	13.58
802.11n	5260	52	15.20	15.18	15.22	15.17	15.26	15.24	15.20	15.21
802.11n	5280	56	15.14	15.16	15.24	15.17	15.20	15.14	15.13	15.15
802.11n	5300	60	15.09	15.10	15.02	15.14	15.16	15.11	15.07	15.14
802.11n	5320	64	13.77	13.64	13.75	13.79	13.74	13.45	13.42	13.35
802.11n	5500	100	13.77	13.68	13.78	13.72	13.70	13.74	13.75	13.69
802.11n	5520	104	15.22	15.20	15.25	15.24	15.18	15.15	15.16	15.17
802.11n	5540	108	15.26	15.25	15.29	15.24	15.25	15.22	15.28	15.32
802.11n	5560	112	15.20	15.24	15.15	15.28	15.20	15.19	15.18	15.13
802.11n	5580	116	15.19	15.14	15.20	15.14	15.23	15.24	15.19	15.16
802.11n	5600	120	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11n	5620	124	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11n	5640	128	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11n	5660	132	15.32	15.30	15.24	15.28	15.22	15.29	15.34	15.33
802.11n	5680	136	15.35	15.32	15.38	15.34	15.30	15.24	15.26	15.28
802.11n	5700	140	13.81	13.80	13.79	13.75	13.69	13.84	13.75	13.74
802.11n	5745	149	15.30	15.36	15.34	15.28	15.25	15.34	15.33	15.30
802.11n	5765	153	15.32	15.28	15.30	15.35	15.24	15.25	15.27	15.26
802.11n	5785	157	15.31	15.42	15.27	15.31	15.44	15.38	15.39	15.41
802.11n	5805	161	15.40	15.36	15.42	15.47	15.34	15.36	15.31	15.38
802.11n	5825	165	15.22	15.26	15.31	15.25	15.28	15.37	15.25	15.24

Table 9-12
IEEE 802.11n Average RF Power – 40MHz Bandwidth

Mode	Freq	Channel	40MHz BW 802.11n (5GHz) Conducted Power [dBm]							
			Data Rate [Mbps]							
	[MHz]		13.5	27	40.5	54	81	108	121.5	135
802.11n	5190	38	10.15	10.14	10.25	10.14	10.16	10.11	10.08	10.09
802.11n	5230	46	10.23	10.20	10.16	10.17	10.18	10.19	10.22	10.25
802.11n	5270	54	10.34	10.40	10.32	10.35	10.39	10.33	10.32	10.34
802.11n	5310	62	10.52	10.50	10.58	10.61	10.52	10.54	10.55	10.50
802.11n	5510	102	10.55	10.52	10.53	10.57	10.55	10.54	10.52	10.56
802.11n	5550	110	10.54	10.53	10.59	10.50	10.46	10.56	10.61	10.57
802.11n	5590	118	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11n	5630	126	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
802.11n	5670	134	10.56	10.54	10.57	10.53	10.56	10.52	10.54	10.50
802.11n	5755	151	10.65	10.63	10.64	10.67	10.60	10.62	10.63	10.64
802.11n	5795	159	10.49	10.64	10.66	10.57	10.53	10.52	10.54	10.56

Table 9-13
IEEE 802.11n Average RF Power – 80MHz Bandwidth

Mode	Freq [MHz]	Channel	80MHz BW 802.11ac (5GHz) Conducted Power [dBm]									
			Data Rate [Mbps]									
			29.3	58.5	87.8	117	175.5	234	263.3	292.5	351	390
			MCS0	MCS1	MCS2	MCS3	MCS4	MCS5	MCS6	MCS7	MCS8	MCS9
802.11ac	5210	42	**10.60**	10.54	10.52	10.57	10.53	10.55	10.59	10.64	10.68	9.94
802.11ac	5290	58	**10.86**	10.78	10.86	10.89	10.86	10.90	10.84	10.88	10.86	10.02
802.11ac	5530	106	**10.88**	10.89	10.87	10.85	10.86	10.87	10.85	10.90	10.91	10.16
802.11ac	5775	155	**10.91**	11.01	10.96	11.02	11.14	11.05	10.92	11.05	10.96	10.18

10. JUSTIFICATION OF HELD TO EAR MODES TESTED

I. Analysis of RF Air Interface Technologies

a. An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes.

The worst case MIF plus the worst case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

II. Individual Mode Evaluations

Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required
EvDO - Rev.A	24.29	-18.33	5.96	No*
EDGE	27.14	4.90	32.04	Yes
UMTS	24.00	-24.86	-0.86	No*
LTE - FDD	23.15	-9.60	13.55	No*
WLAN	15.47	-12.63	2.84	No*

Table 10-1
Max Power + MIF calculations
for Low Power Exemptions

III. Low-Power Exemption Conclusions

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for EDGE transmit mode. All other air interfaces are exempt from required testing.

*** Note:** Despite having MIF+power values that would allow exemption from testing, these modes were tested for HAC RFE as if they were not exempt.

11. OVERALL MEASUREMENT SUMMARY

FCC ID:	ACJEB3910A
Model:	FZ-X1
S/N:	#049

I. E-FIELD EMISSIONS:

Table 11-1
HAC Data Summary for EvDO E-field

Mode	Channel	Rev.	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
E-field Emissions												
Cell. EvDO	1013	Rev.A	Acoustic	24.29	43.55	32.78	-18.37	14.41	45.00	-30.59	M4	none
Cell. EvDO	384	Rev.A	Acoustic	24.21	36.01	31.13	-18.44	12.69	45.00	-32.31	M4	none
Cell. EvDO	777	Rev.A	Acoustic	24.14	47.82	33.59	-18.36	15.23	45.00	-29.77	M4	none
PCS EvDO	25	Rev.A	Acoustic	23.55	32.46	30.23	-18.69	11.54	35.00	-23.46	M4	none
PCS EvDO	600	Rev.A	Acoustic	23.61	26.34	28.41	-19.26	9.15	35.00	-25.85	M4	none
PCS EvDO	1175	Rev.A	Acoustic	23.84	25.84	28.25	-18.33	9.92	35.00	-25.08	M4	none
PCS EvDO	25	Rev.A	T-coil	23.55	32.46	30.23	-18.69	11.54	35.00	-23.46	M4	none

Table 11-2
HAC Data Summary for EDGE E-field

Mode	Channel	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
E-field Emissions											
EDGE850	128	Acoustic	27.03	36.64	31.28	4.90	36.18	45.00	-8.82	M4	none
EDGE850	190	Acoustic	27.14	34.37	30.72	4.90	35.62	45.00	-9.38	M4	none
EDGE850	251	Acoustic	27.07	43.37	32.74	4.32	37.06	45.00	-7.94	M4	none
EDGE1900	512	Acoustic	26.05	23.10	27.27	4.45	31.72	35.00	-3.28	M3	none
EDGE1900	661	Acoustic	26.08	21.44	26.62	4.21	30.83	35.00	-4.17	M3	none
EDGE1900	810	Acoustic	26.12	18.09	25.15	4.29	29.44	35.00	-5.56	M4	none
EDGE1900	512	T-coil	26.05	23.10	27.27	4.45	31.72	35.00	-3.28	M3	none

Table 11-3
HAC Data Summary for UMTS E-field

Mode	Channel	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
E-field Emissions											
UMTS V	4132	Acoustic	23.96	41.29	32.32	-25.19	7.13	45.00	-37.87	M4	none
UMTS V	4183	Acoustic	23.98	33.92	30.61	-26.04	4.57	45.00	-40.43	M4	none
UMTS V	4233	Acoustic	23.98	42.44	32.56	-25.93	6.63	45.00	-38.37	M4	none
UMTS II	9262	Acoustic	23.92	29.86	29.50	-27.33	2.17	35.00	-32.83	M4	none
UMTS II	9400	Acoustic	23.95	27.01	28.63	-27.72	0.91	35.00	-34.09	M4	none
UMTS II	9538	Acoustic	24.00	25.16	28.01	-24.86	3.15	35.00	-31.85	M4	none

Table 11-4
HAC Data Summary for LTE E-field

Band	Channel	Bandwidth (MHz)	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
E-field Emissions															
17	23790	10	16QAM	1	25	Acoustic	22.04	43.54	32.78	-9.80	22.98	45.00	-22.02	M4	none
13	23230	10	16QAM	1	25	Acoustic	21.98	37.60	31.50	-9.83	21.67	45.00	-23.33	M4	none
4	20175	10	16QAM	1	25	Acoustic	22.06	25.86	28.25	-9.60	18.65	35.00	-16.35	M4	none

Table 11-5
HAC Data Summary for WLAN E-field

Mode	Channel	Data Rate	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
E-field Emissions												
802.11b	6	11Mbps	Acoustic	14.76	16.35	24.27	-12.63	11.64	35.00	-23.36	M4	none
802.11a	149	54Mbps	Acoustic	15.44	10.55	20.47	-14.43	6.04	35.00	-28.96	M4	none
802.11n (20MHz)	157	65Mbps	Acoustic	15.41	12.31	21.81	-14.38	7.43	35.00	-27.57	M4	none

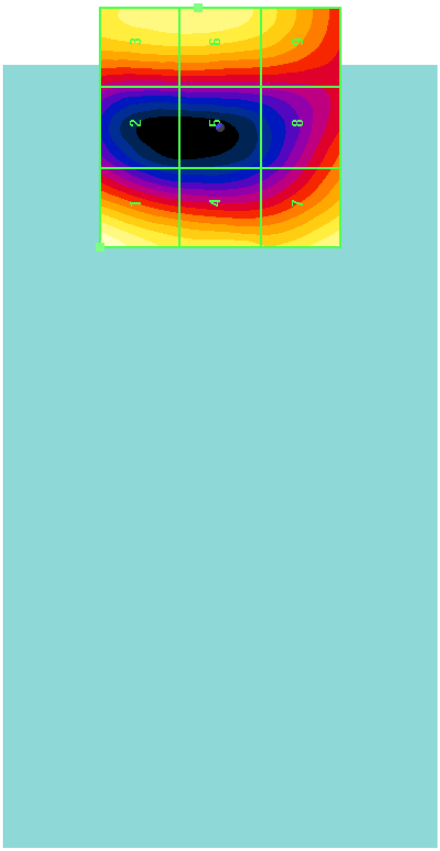


Figure 11-1
Sample E-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

II. Worst-case Configuration Evaluation

Table 11-6
Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Channel	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT
Probe Rotation at Worst-Case									
EDGE1900	512	Acoustic	24.34	27.73	4.45	32.18	**35.00**	-2.82	M3

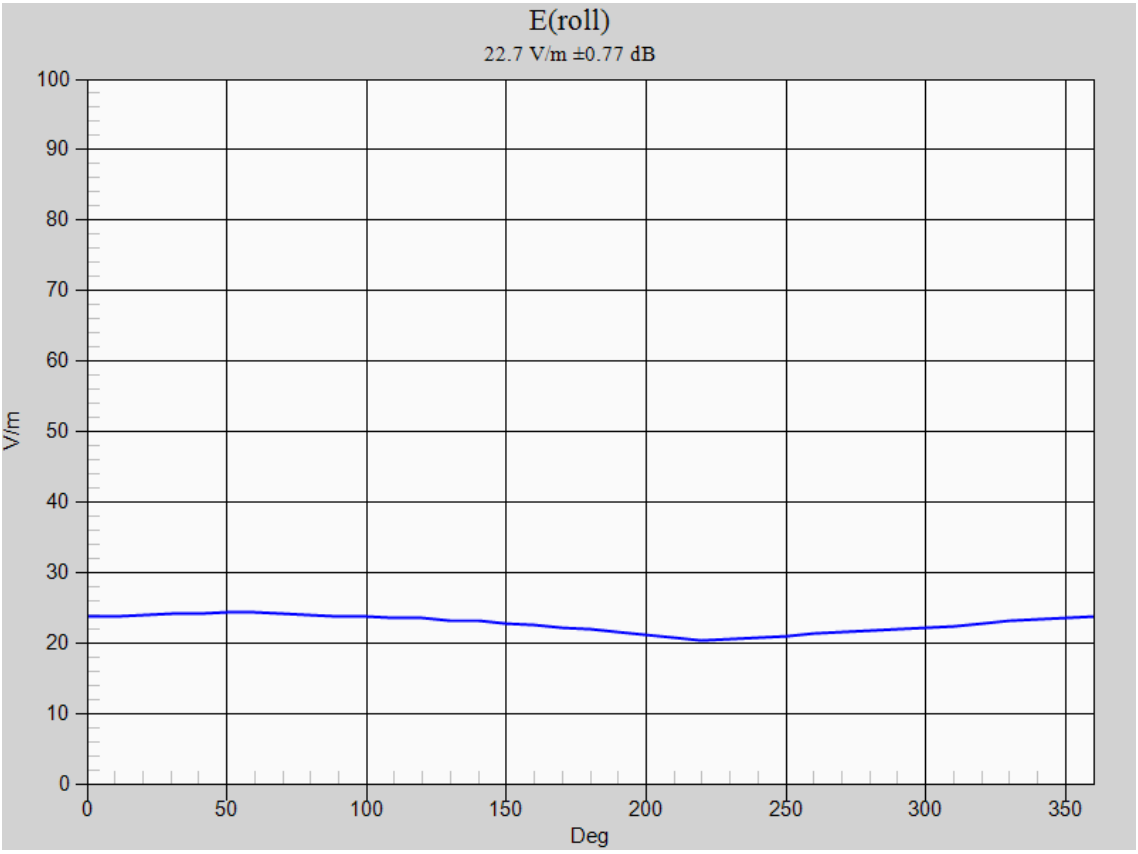


Figure 11-2
Worst-Case Probe Rotation about Azimuth axis

* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

12. EQUIPMENT LIST

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4407B	ESA Spectrum Analyzer	4/16/2013	Annual	4/16/2014	US39210313
Agilent	E4432B	ESG-D Series Signal Generator	4/17/2013	Annual	4/17/2014	US40053896
Agilent	N5182A	MXG Vector Signal Generator	10/28/2013	Annual	10/28/2014	US46240505
Agilent	E5515C	Wireless Communications Test Set	10/18/2012	Biennial	10/18/2014	GB43193563
Agilent	E5515C	Wireless Communications Test Set	5/9/2013	Biennial	5/9/2015	GB43304447
Amplifier Research	5S1G4	5W, 800MHz-4.2GHz	N/A	CBT*	N/A	21910
Anritsu	ML2438A	Power Meter	2/14/2013	Annual	2/14/2014	1190013
Anritsu	MA2481A	Power Sensor	2/14/2013	Annual	2/14/2014	5318
Anritsu	MA2411B	Pulse Power Sensor	11/14/2013	Annual	11/14/2014	1126066
Anritsu	MT8820C	Radio Communication Analyzer	6/28/2013	Annual	6/28/2014	6201240328
Anritsu	MT8820C	Radio Communication Analyzer	12/12/2013	Annual	12/12/2014	6201300731
Anritsu	MA24106A	USB Power Sensor	1/3/2014	Annual	1/3/2015	1349501
L-Com	HG824-11LP	Log Periodic Antenna	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Pasternack	PE2208-6	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Pasternack	PE2209-10	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMU200	Base Station Simulator	5/3/2013	Annual	5/3/2014	836371/0079
Rohde & Schwarz	CMU200	Base Station Simulator	9/23/2013	Annual	9/23/2014	109892
Rohde & Schwarz	NRVD	Dual Channel Power Meter	10/12/2012	Biennial	10/12/2014	101695
Rohde & Schwarz	CMW500	LTE Radio Communication Tester	10/4/2013	Biennial	10/4/2015	103962
Rohde & Schwarz	NRV-Z32	Peak Power Sensor	10/12/2012	Biennial	10/12/2014	836019/013
Rohde & Schwarz	NRV-Z32	Peak Power Sensor (100uW-2W)	10/11/2012	Biennial	10/11/2014	100155
Rohde & Schwarz	NRV-Z32	Peak Power Sensor (1mW-20W)	10/31/2013	Annual	10/31/2014	100004
Rohde & Schwarz	SME06	Signal Generator	10/30/2013	Annual	10/30/2014	832026
Rohde & Schwarz	NRVS	Single Channel Power Meter	10/31/2013	Annual	10/31/2014	835360/0079
Seekonk	NC-100	Torque Wrench (8" lb)	11/29/2011	Triennial	11/29/2014	21053
Speag	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	DAE4	Dasy Data Acquisition Electronics	4/22/2013	Annual	4/22/2014	665
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/5/2013	Biennial	2/5/2015	1137
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/5/2013	Biennial	2/5/2015	1003
SPEAG	ER3DV6	Freespace E-field Probe	8/23/2013	Annual	8/23/2014	2335

Table 12-1
Equipment List

Calibration traceable to the National Institute of Standards and Technology (NIST).

***Note: CBT (Calibrated Before Testing).** Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

13. MEASUREMENT UNCERTAINTY

Wireless Communications Device Near-Field Measurement Uncertainty Estimation							
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
Measurement System							
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Probe Modulation Factor	0.270	Accuracy	R	1.73	1	0.16	
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.210	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	
Test Sample Related							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)						0.66	16.5%
Expanded Uncertainty [95% confidence] (k=2)						1.33	32.3%
Expanded Uncertainty [95% confidence] on Field						**0.66**	**16.2%**

Table 13-1
Uncertainty Estimation Table

Notes:
1. Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81 and NIST Tech Note 1297 and UKAS M3003.
2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

14. TEST DATA

See following Attached Pages for Test Data.

Date: 01/06/2014

PCTEST Hearing-Aid Compatibility Facility

DUT: CD835V3 - SN1003

Type: CD835V3
Serial: 1003

Communication System: CW; Frequency: 835 MHz;

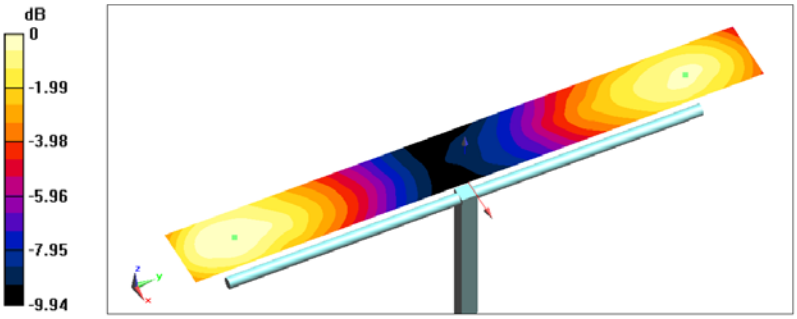
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 108.8 V/m; Power Drift = 0.13 dB
Applied MIF = 0.00 dB
Average value of Peak (interpolated) = 100.1 V/m



0 dB = 102.3 V/m = 40.20 dBV/m

Date: 01/06/2014

PCTEST Hearing-Aid Compatibility Facility

DUT: CD1880V3 - SN1137

Type: CD1880V3
Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

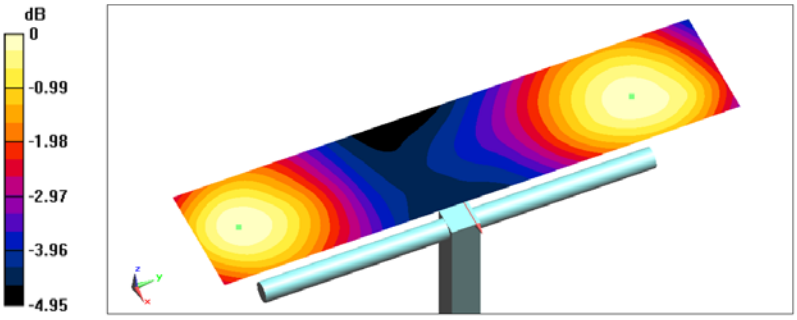
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 134.8 V/m; Power Drift = -0.10 dB
Applied MIF = 0.00 dB
Average value of Peak (interpolated) = 91.9 V/m



0 dB = 92.10 V/m = 39.29 dBV/m

Date: 01/10/2014

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:1

Communication System: CDMA; Frequency: 848.31 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

Cell. EvDO Rev.A High Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 54.17 V/m; Power Drift = -0.12 dB
Applied MIF = -18.36 dB
RF audio interference level = 15.23 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **13.95 dBV/m**	Grid 2 **M4** **14.64 dBV/m**	Grid 3 **M4** **14.61 dBV/m**
Grid 4 **M4** **14.31 dBV/m**	Grid 5 **M4** **14.79 dBV/m**	Grid 6 **M4** **14.8 dBV/m**
Grid 7 **M4** **15 dBV/m**	Grid 8 **M4** **15.23 dBV/m**	Grid 9 **M4** **14.9 dBV/m**

0 dB = 5.776 V/m = 15.23 dBV/m

Date: 01/10/2014

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:1

Communication System: CDMA; Frequency: 1851.25 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

PCS EvDO Rev.A Low Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 20.62 V/m; Power Drift = -0.03 dB
Applied MIF = -18.69 dB
RF audio interference level = 11.54 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **10.96 dBV/m**	Grid 2 **M4** **10.07 dBV/m**	Grid 3 **M4** **11.4 dBV/m**
Grid 4 **M4** **9.12 dBV/m**	Grid 5 **M4** **10.08 dBV/m**	Grid 6 **M4** **11.54 dBV/m**
Grid 7 **M4** **10.15 dBV/m**	Grid 8 **M4** **9.57 dBV/m**	Grid 9 **M4** **10.64 dBV/m**

0 dB = 3.775 V/m = 11.54 dBV/m

Date: 01/09/2014

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM EGPRS; 1 Tx slot; Frequency: 848.8 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

EGPRS 850, High Channel, 1Tx Slot/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 45.72 V/m; Power Drift = 0.19 dB
Applied MIF = 4.32 dB
RF audio interference level = 37.06 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **34.31 dBV/m**	Grid 2 **M4** **36.15 dBV/m**	Grid 3 **M4** **36.33 dBV/m**
Grid 4 **M4** **35 dBV/m**	Grid 5 **M4** **36.66 dBV/m**	Grid 6 **M4** **36.83 dBV/m**
Grid 7 **M4** **35.79 dBV/m**	Grid 8 **M4** **37.01 dBV/m**	Grid 9 **M4** **37.06 dBV/m**

0 dB = 71.31 V/m = 37.06 dBV/m

Date: 01/09/2014

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM EGPRS; 1 Tx slot; Frequency: 1850.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

EGPRS 1900, Low Channel, 1Tx Slot/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 9.821 V/m; Power Drift = -0.02 dB
Applied MIF = 4.45 dB
RF audio interference level = 31.72 dBV/m
Emission category: M3

MIF scaled E-field

Grid 1 **M3** **31.72 dBV/m**	Grid 2 **M4** **28.06 dBV/m**	Grid 3 **M3** **31.2 dBV/m**
Grid 4 **M3** **30.81 dBV/m**	Grid 5 **M4** **27.79 dBV/m**	Grid 6 **M3** **31.26 dBV/m**
Grid 7 **M3** **31.42 dBV/m**	Grid 8 **M4** **29.29 dBV/m**	Grid 9 **M3** **30.68 dBV/m**

0 dB = 38.55 V/m = 31.72 dBV/m

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:1

Communication System: UMTS; Frequency: 826.4 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

UMTS 850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 45.42 V/m; Power Drift = -0.00 dB
Applied MIF = -25.19 dB
RF audio interference level = 7.13 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **5.68 dBV/m**	Grid 2 **M4** **6.62 dBV/m**	Grid 3 **M4** **6.62 dBV/m**
Grid 4 **M4** **6.13 dBV/m**	Grid 5 **M4** **6.95 dBV/m**	Grid 6 **M4** **6.95 dBV/m**
Grid 7 **M4** **6.65 dBV/m**	Grid 8 **M4** **7.13 dBV/m**	Grid 9 **M4** **7.11 dBV/m**

0 dB = 2.272 V/m = 7.13 dBV/m

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:1

Communication System: UMTS; Frequency: 1907.6 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

UMTS 1900 High Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 12.34 V/m; Power Drift = 0.11 dB
Applied MIF = -24.86 dB
RF audio interference level = 3.15 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **0.76 dBV/m**	Grid 2 **M4** **-0.99 dBV/m**	Grid 3 **M4** **0.32 dBV/m**
Grid 4 **M4** **1.31 dBV/m**	Grid 5 **M4** **-0.73 dBV/m**	Grid 6 **M4** **0.27 dBV/m**
Grid 7 **M4** **3.15 dBV/m**	Grid 8 **M4** **2.27 dBV/m**	Grid 9 **M4** **0.97 dBV/m**

0 dB = 1.438 V/m = 3.16 dBV/m

Date: 01/10/2014

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:1

Communication System: LTE Band 4; Frequency: 1732.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

LTE Band 4: ch.20175, 10MHz BW, 1RB, 25RB offset, 16QAM/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 19.32 V/m; Power Drift = 0.18 dB
Applied MIF = -9.60 dB
RF audio interference level = 18.65 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **18.65 dBV/m**	Grid 2 **M4** **17.11 dBV/m**	Grid 3 **M4** **18.21 dBV/m**
Grid 4 **M4** **15.73 dBV/m**	Grid 5 **M4** **17.36 dBV/m**	Grid 6 **M4** **18.34 dBV/m**
Grid 7 **M4** **17.2 dBV/m**	Grid 8 **M4** **17.11 dBV/m**	Grid 9 **M4** **17.8 dBV/m**

0 dB = 8.562 V/m = 18.65 dBV/m

PCTEST Hearing-Aid Compatibility Facility

DUT: ACJEB3910A

Type: Portable Handset
Serial: #049
Backlight off
Duty Cycle: 1:1

Communication System: IEEE 802.11b; Frequency: 2437 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/23/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

WLAN 802.11b: ch.6, 11Mbps/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 7.885 V/m; Power Drift = -0.13 dB
Applied MIF = -12.63 dB
RF audio interference level = 11.64 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **9.41 dBV/m**	Grid 2 **M4** **11.64 dBV/m**	Grid 3 **M4** **11.58 dBV/m**
Grid 4 **M4** **6.34 dBV/m**	Grid 5 **M4** **9.19 dBV/m**	Grid 6 **M4** **9.56 dBV/m**
Grid 7 **M4** **4.44 dBV/m**	Grid 8 **M4** **7.79 dBV/m**	Grid 9 **M4** **8.57 dBV/m**

0 dB = 3.820 V/m = 11.64 dBV/m

15. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client PC Test

Certificate No: ER3-2335_Aug13

CALIBRATION CERTIFICATE

Object: ER3DV6 - SN:2335

Calibration procedure(s): QA CAL-02.v8, QA CAL-25.v6
Calibration procedure for E-field probes optimized for close near field evaluations in air

Calibration date: August 23, 2013

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	04-Apr-13 (No. 217-01733)	Apr-14
Power sensor E4412A	MY41498087	04-Apr-13 (No. 217-01733)	Apr-14
Reference 3 dB Attenuator	SN: S5054 (3c)	04-Apr-13 (No. 217-01737)	Apr-14
Reference 20 dB Attenuator	SN: S5277 (20x)	04-Apr-13 (No. 217-01735)	Apr-14
Reference 30 dB Attenuator	SN: S5129 (30b)	04-Apr-13 (No. 217-01738)	Apr-14
Reference Probe ER3DV6	SN: 2328	12-Oct-12 (No. ER3-2328_Oct12)	Oct-13
DAE4	SN: 789	15-May-13 (No. DAE4-789_May13)	May-14
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-13)	In house check: Apr-15
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-12)	In house check: Oct-13

	Name	Function	Signature
Calibrated by:	Leif Klysner	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: August 23, 2013

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C, D	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
b) CTIA Test Plan for Hearing Aid Compatibility, April 2010.

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *NORM(f)x,y,z = NORMx,y,z * frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *PAR:* PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- *Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. *VR* is the maximum calibration range expressed in RMS voltage across the diode.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORMx* (no uncertainty required).

Probe ER3DV6

SN:2335

Manufactured: September 9, 2003
Calibrated: August 23, 2013

Calibrated for DASY/EASY Systems
(Note: non-compatible with DASY2 system!)

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu V/(V/m)^2$)	1.64	1.70	1.87	± 10.1 %
DCP (mV)[B]	97.7	98.6	100.6	

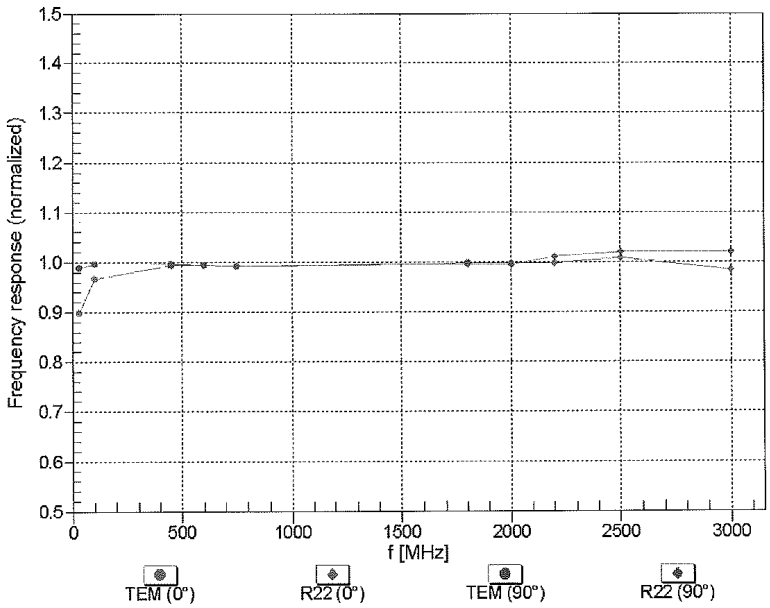
Modulation Calibration Parameters

UID	Communication System Name		A dB	B dB√μV	C	D dB	VR mV	Unc[E] (k=2)
0	CW	X	0.0	0.0	1.0	0.00	152.3	±2.7 %
		Y	0.0	0.0	1.0		163.1	
		Z	0.0	0.0	1.0		191.7	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[B] Numerical linearization parameter: uncertainty not required.
[E] Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

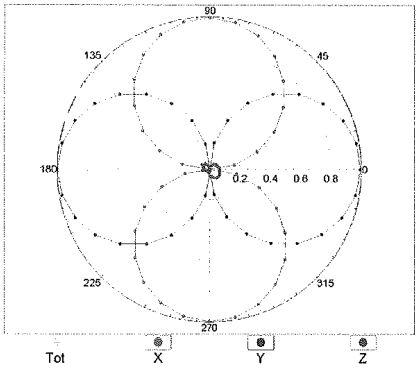
Frequency Response of E-Field
(TEM-Cell:ifi110 EXX, Waveguide: R22)



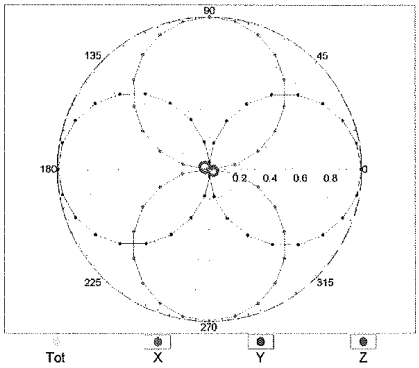
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

Receiving Pattern (ϕ), ϑ = 0°

f=600 MHz,TEM,0°

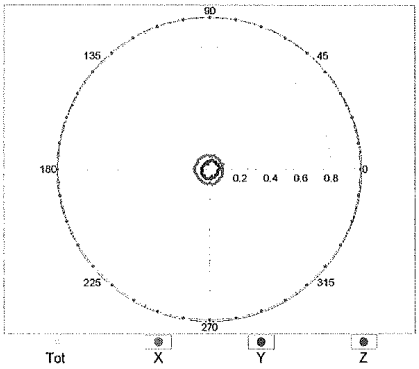


f=2500 MHz,R22,0°

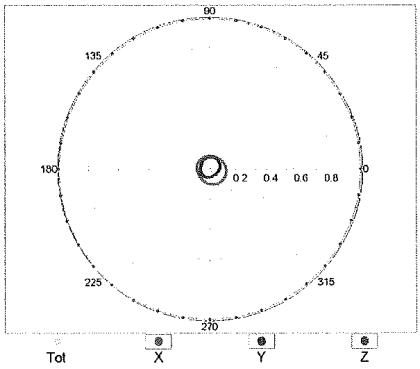


Receiving Pattern (ϕ), ϑ = 90°

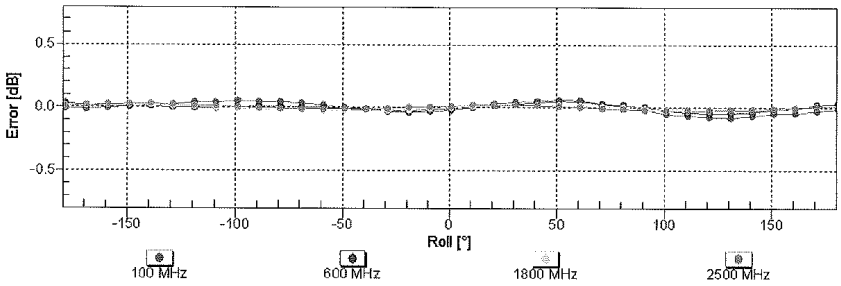
f=600 MHz,TEM,90°



f=2500 MHz,R22,90°

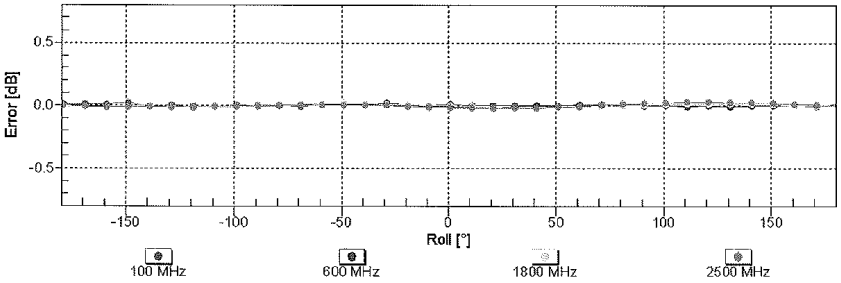


Receiving Pattern (ϕ), ϑ = 0°



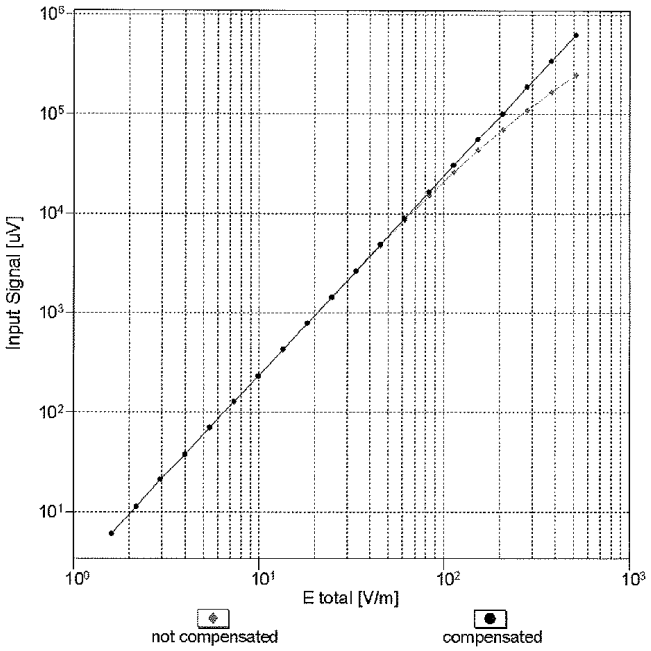
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

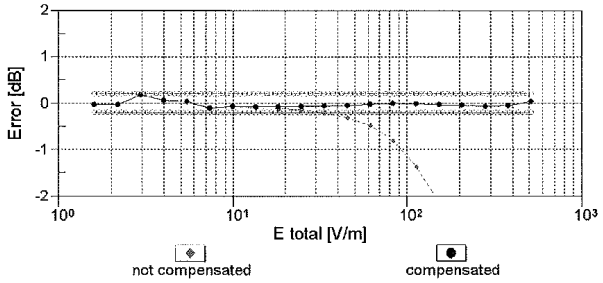
Receiving Pattern (ϕ), ϑ = 90°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Dynamic Range f(E-field)
(TEM cell , f = 900 MHz)

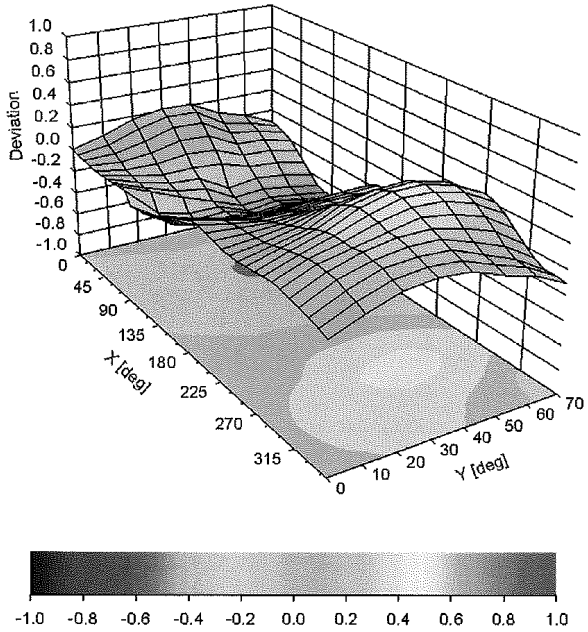




Uncertainty of Linearity Assessment: ± 0.6% (k=2)

Deviation from Isotropy in Air

Error (ϕ, ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-99
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client PC Test

Certificate No: CD835V3-1003_Feb13

CALIBRATION CERTIFICATE

Object	CD835V3 - SN: 1003
Calibration procedure(s)	QA CAL-20.v6 Calibration procedure for dipoles in air
Calibration date:	February 05, 2013

KOK 2/21/13

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	01-Nov-12 (No. 217-01640)	Oct-13
Power sensor HP 8481A	US37292783	01-Nov-12 (No. 217-01640)	Oct-13
Reference 10 dB Attenuator	SN: 5047.2 (10q)	27-Mar-12 (No. 217-01527)	Apr-13
Probe ER3DV6	SN: 2336	28-Dec-12 (No. ER3-2336_Dec12)	Dec-13
Probe H3DV6	SN: 6065	28-Dec-12 (No. H3-6065_Dec12)	Dec-13
DAE4	SN: 781	29-May-12 (No. DAE4-781_May12)	May-13

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-12)	In house check: Oct-13
Power sensor HP E4412A	SN: MY41495277	01-Apr-08 (in house check Oct-12)	In house check: Oct-13
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-12)	In house check: Oct-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-12)	In house check: Oct-13
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-12)	In house check: Oct-14

	Name	Function	Signature
Calibrated by:	Dimce Iliev	Laboratory Technician	D. Iliev
Approved by:	Katja Pokovic	Technical Manager	

Issued: February 6, 2013

References

[1] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

[2] ANSI-C63.19-2011
American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm (15 mm for [2]) above the top metal edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
  It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E-field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1] and [2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (15 mm for [2]) (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.5
Extrapolation	Advanced Extrapolation	
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10mm 15mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 835 MHz

H-field 10 mm above dipole surface	condition	**interpolated maximum**
Maximum measured	100 mW input power	**0.470 A / m ± 8.2 % (k=2)**

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	169.8 V / m
Maximum measured above low end	100 mW input power	164.4 V / m
Averaged maximum above arm	100 mW input power	**167.1 V / m ± 12.8 % (k=2)**

E-field 15 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	108.3 V / m
Maximum measured above low end	100 mW input power	107.0 V / m
Averaged maximum above arm	100 mW input power	**107.7 V / m ± 12.8 % (k=2)**

Appendix

Antenna Parameters

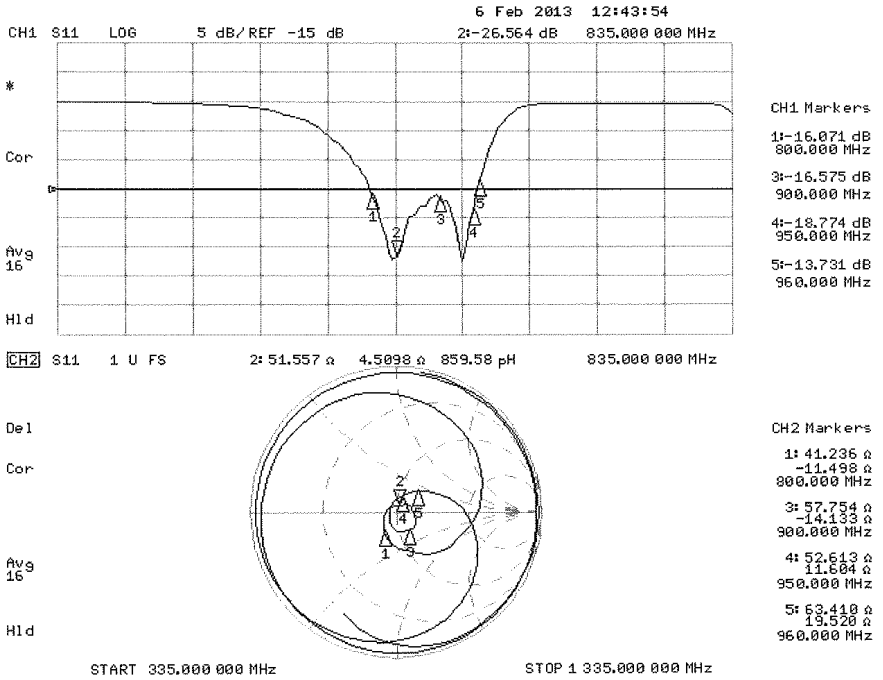
Frequency	Return Loss	Impedance
800 MHz	16.1 dB	41.2 Ω - 11.5 jΩ
835 MHz	26.6 dB	51.6 Ω + 4.5 jΩ
900 MHz	16.6 dB	57.8 Ω - 14.1 jΩ
950 MHz	18.8 dB	52.6 Ω + 11.6 jΩ
960 MHz	13.7 dB	63.4 Ω + 19.5 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Impedance Measurement Plot



DASY5 H-field Result

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1003

Communication System: CW; Frequency: 835 MHz
Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

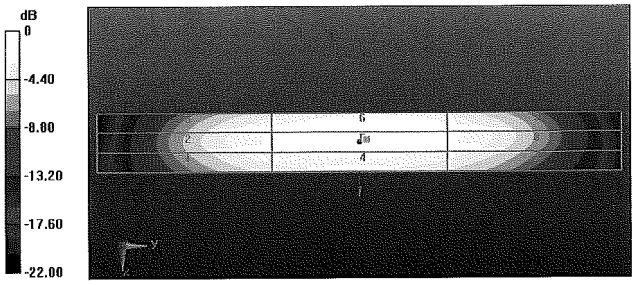
DASY52 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 28.12.2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

Dipole H-Field measurement @ 835MHz/H-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.4980 A/m; Power Drift = -0.01 dB
PMR not calibrated. PMF = 1.000 is applied.
H-field emissions = 0.4697 A/m
Near-field category: M4 (AWF 0 dB)

PMF scaled H-field

Grid 1 **M4** **0.380 A/m**	Grid 2 **M4** **0.413 A/m**	Grid 3 **M4** **0.399 A/m**
Grid 4 **M4** **0.427 A/m**	Grid 5 **M4** **0.470 A/m**	Grid 6 **M4** **0.460 A/m**
Grid 7 **M4** **0.369 A/m**	Grid 8 **M4** **0.413 A/m**	Grid 9 **M4** **0.406 A/m**



0 dB = 0.4697 A/m = -6.56 dBA/m

DASY5 E-field Result

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1003

Communication System: CW; Frequency: 835 MHz
Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 28.12.2012;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 112.7 V/m; Power Drift = -0.01 dB
PMR not calibrated. PMF = 1.000 is applied.
E-field emissions = 169.8 V/m
Near-field category: M4 (AWF 0 dB)

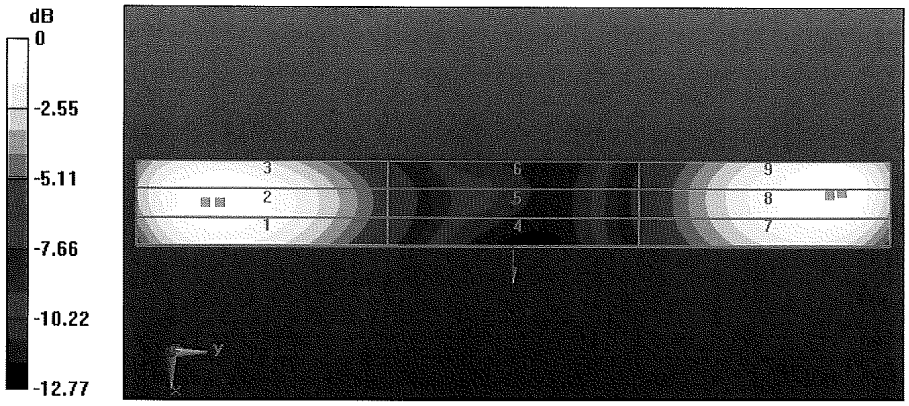
PMF scaled E-field

Grid 1 **M4** **159.6 V/m**	Grid 2 **M4** **164.4 V/m**	Grid 3 **M4** **159.2 V/m**
Grid 4 **M4** **86.08 V/m**	Grid 5 **M4** **89.03 V/m**	Grid 6 **M4** **87.03 V/m**
Grid 7 **M4** **155.8 V/m**	Grid 8 **M4** **169.8 V/m**	Grid 9 **M4** **169.5 V/m**

Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 112.1 V/m; Power Drift = -0.03 dB
PMR not calibrated. PMF = 1.000 is applied.
E-field emissions = 108.3 V/m
Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 **M4** **105.2 V/m**	Grid 2 **M4** **107.0 V/m**	Grid 3 **M4** **105.3 V/m**
Grid 4 **M4** **62.40 V/m**	Grid 5 **M4** **63.62 V/m**	Grid 6 **M4** **62.80 V/m**
Grid 7 **M4** **104.3 V/m**	Grid 8 **M4** **108.3 V/m**	Grid 9 **M4** **107.9 V/m**



0 dB = 169.8 V/m = 44.60 dBV/m

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client PC Test

Certificate No: CD1880V3-1137_Feb13

CALIBRATION CERTIFICATE

Object: CD1880V3 - SN: 1137

Calibration procedure(s): QA CAL-20.v6
Calibration procedure for dipoles in air

Calibration date: February 05, 2013

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	01-Nov-12 (No. 217-01640)	Oct-13
Power sensor HP 8481A	US37292783	01-Nov-12 (No. 217-01640)	Oct-13
Reference 10 dB Attenuator	SN: 5047.2 (10q)	27-Mar-12 (No. 217-01527)	Apr-13
Probe ER3DV6	SN: 2336	28-Dec-12 (No. ER3-2336_Dec12)	Dec-13
Probe H3DV6	SN: 6065	28-Dec-12 (No. H3-6065_Dec12)	Dec-13
DAE4	SN: 781	29-May-12 (No. DAE4-781_May12)	May-13

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-12)	In house check: Oct-13
Power sensor HP E4412A	SN: MY41495277	01-Apr-08 (in house check Oct-12)	In house check: Oct-13
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-12)	In house check: Oct-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-12)	In house check: Oct-13
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-12)	In house check: Oct-14

	Name	Function	Signature
Calibrated by:	Dimce Iliev	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: February 6, 2013

References

[1] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

[2] ANSI-C63.19-2011
American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm (15 mm for [2]) above the top metal edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
  It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E-field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1] and [2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (15 mm for [2]) (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.5
Extrapolation	Advanced Extrapolation	
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10mm 15mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 1730 MHz

H-field 10 mm above dipole surface	condition	**interpolated maximum**
Maximum measured	100 mW input power	**0.493 A / m ± 8.2 % (k=2)**

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	154.1 V / m
Maximum measured above low end	100 mW input power	150.3 V / m
Averaged maximum above arm	100 mW input power	**152.2 V / m ± 12.8 % (k=2)**

E-field 15 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	98.6 V / m
Maximum measured above low end	100 mW input power	97.6 V / m
Averaged maximum above arm	100 mW input power	**98.1 V / m ± 12.8 % (k=2)**

Maximum Field values at 1880 MHz

H-field 10 mm above dipole surface	condition	**interpolated maximum**
Maximum measured	100 mW input power	**0.467 A / m ± 8.2 % (k=2)**

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	140.1 V / m
Maximum measured above low end	100 mW input power	139.2 V / m
Averaged maximum above arm	100 mW input power	**139.7 V / m ± 12.8 % (k=2)**

E-field 15 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	91.7 V / m
Maximum measured above low end	100 mW input power	88.7 V / m
Averaged maximum above arm	100 mW input power	**90.2 V / m ± 12.8 % (k=2)**

Appendix

Antenna Parameters

Nominal Frequencies

Frequency	Return Loss	Impedance
1730 MHz	22.1 dB	48.6 Ω + 7.7 jΩ
1880 MHz	20.4 dB	50.2 Ω + 9.6 jΩ
1900 MHz	21.0 dB	53.6 Ω + 8.5 jΩ
1950 MHz	27.3 dB	54.5 Ω + 0.0 jΩ
2000 MHz	20.1 dB	41.0 Ω - 1.2 jΩ

Additional Frequencies

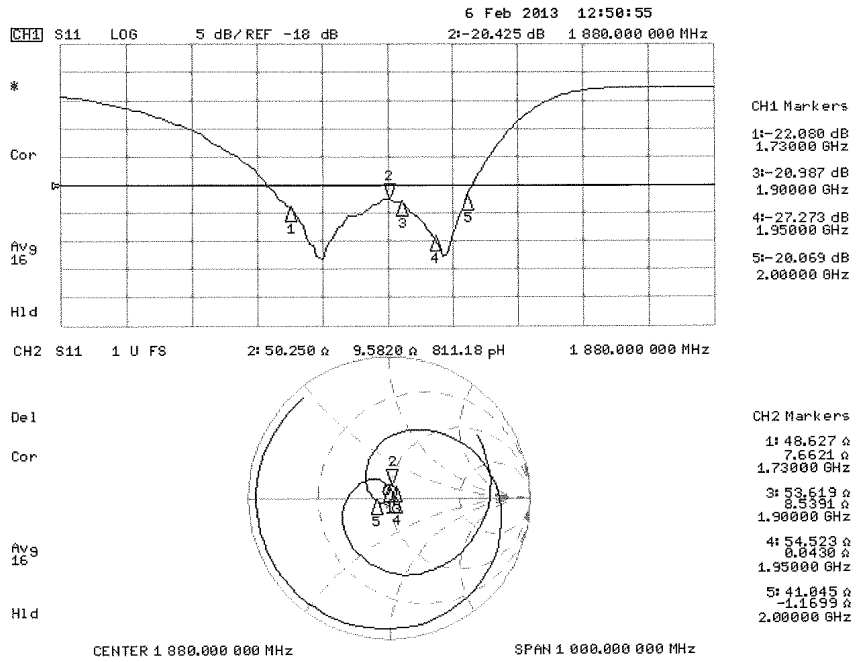
Frequency	Return Loss	Impedance
1730 MHz	22.1 dB	48.6 Ω + 7.7 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Impedance Measurement Plot



DASY5 H-field Result

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: CW; Frequency: 1730 MHz, Frequency: 1880 MHz
Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 28.12.2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

Dipole H-Field measurement @ 1880MHz/H-Scan - 1730MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.5230 A/m; Power Drift = -0.02 dB
PMR not calibrated. PMF = 1.000 is applied.
H-field emissions = 0.4933 A/m
Near-field category: M2 (AWF 0 dB)

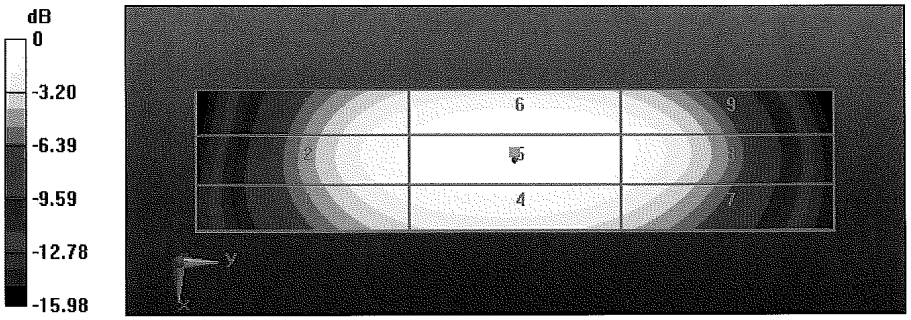
PMF scaled H-field

Grid 1 **M2** **0.406 A/m**	Grid 2 **M2** **0.437 A/m**	Grid 3 **M2** **0.425 A/m**
Grid 4 **M2** **0.453 A/m**	Grid 5 **M2** **0.493 A/m**	Grid 6 **M2** **0.482 A/m**
Grid 7 **M2** **0.394 A/m**	Grid 8 **M2** **0.434 A/m**	Grid 9 **M2** **0.425 A/m**

Dipole H-Field measurement @ 1880MHz/H-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.4940 A/m; Power Drift = 0.02 dB
PMR not calibrated. PMF = 1.000 is applied.
H-field emissions = 0.4674 A/m
Near-field category: M2 (AWF 0 dB)

PMF scaled H-field

Grid 1 **M2** **0.404 A/m**	Grid 2 **M2** **0.431 A/m**	Grid 3 **M2** **0.418 A/m**
Grid 4 **M2** **0.436 A/m**	Grid 5 **M2** **0.467 A/m**	Grid 6 **M2** **0.455 A/m**
Grid 7 **M2** **0.393 A/m**	Grid 8 **M2** **0.428 A/m**	Grid 9 **M2** **0.417 A/m**



0 dB = 0.4933 A/m = -6.14 dBA/m

DASY5 E-field Result

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: CW; Frequency: 1730 MHz, Frequency: 1880 MHz
Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 28.12.2012;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

Dipole E-Field measurement @ 1880MHz/E-Scan - 1730MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 167.8 V/m; Power Drift = -0.03 dB
PMR not calibrated. PMF = 1.000 is applied.
E-field emissions = 154.1 V/m
Near-field category: M2 (AWF 0 dB)

PMF scaled E-field

Grid 1 **M2** **143.6 V/m**	Grid 2 **M2** **150.3 V/m**	Grid 3 **M2** **148.3 V/m**
Grid 4 **M3** **99.24 V/m**	Grid 5 **M3** **103.5 V/m**	Grid 6 **M3** **100.7 V/m**
Grid 7 **M2** **141.6 V/m**	Grid 8 **M2** **154.1 V/m**	Grid 9 **M2** **153.3 V/m**

Dipole E-Field measurement @ 1880MHz/E-Scan - 1730MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 167.4 V/m; Power Drift = 0.00 dB
PMR not calibrated. PMF = 1.000 is applied.
E-field emissions = 98.59 V/m
Near-field category: M3 (AWF 0 dB)

PMF scaled E-field

Grid 1 **M3** **95.62 V/m**	Grid 2 **M3** **98.59 V/m**	Grid 3 **M3** **97.71 V/m**
Grid 4 **M3** **75.59 V/m**	Grid 5 **M3** **77.10 V/m**	Grid 6 **M3** **76.15 V/m**
Grid 7 **M3** **93.67 V/m**	Grid 8 **M3** **97.64 V/m**	Grid 9 **M3** **97.16 V/m**

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 152.4 V/m; Power Drift = -0.01 dB
PMR not calibrated. PMF = 1.000 is applied.
E-field emissions = 140.1 V/m
Near-field category: M2 (AWF 0 dB)

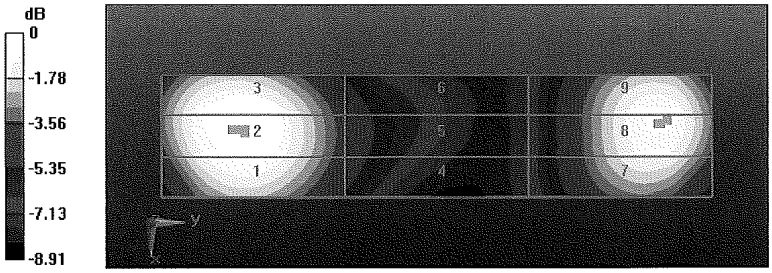
PMF scaled E-field

Grid 1 **M2** **133.0 V/m**	Grid 2 **M2** **139.2 V/m**	Grid 3 **M2** **137.5 V/m**
Grid 4 **M3** **87.01 V/m**	Grid 5 **M3** **90.38 V/m**	Grid 6 **M3** **87.88 V/m**
Grid 7 **M2** **128.4 V/m**	Grid 8 **M2** **140.1 V/m**	Grid 9 **M2** **139.5 V/m**

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 152.6 V/m; Power Drift = -0.03 dB
PMR not calibrated. PMF = 1.000 is applied.
E-field emissions = 91.71 V/m
Near-field category: M3 (AWF 0 dB)

PMF scaled E-field

Grid 1 **M3** **89.14 V/m**	Grid 2 **M3** **91.70 V/m**	Grid 3 **M3** **90.76 V/m**
Grid 4 **M3** **69.64 V/m**	Grid 5 **M3** **70.74 V/m**	Grid 6 **M3** **69.97 V/m**
Grid 7 **M3** **85.07 V/m**	Grid 8 **M3** **88.71 V/m**	Grid 9 **M3** **88.36 V/m**



0 dB = 154.1 V/m = 43.76 dBV/m

16. CONCLUSION

The measurements indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

17. REFERENCES

1. ANSI/IEEE C63.19-2011, American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids.", New York, NY, IEEE, May 2011

2. Berger, H. S., "Compatibility Between Hearing Aids and Wireless Devices," Electronic Industries Forum, Boston, MA, May, 1997

3. Berger, H. S., "Hearing Aid and Cellular Phone Compatibility: Working Toward Solutions," Wireless Telephones and Hearing Aids: New Challenges for Audiology, Gallaudet University, Washington, D.C., May, 1997 (To be reprinted in the American Journal of Audiology).

4. Berger, H. S., "Hearing Aid Compatibility with Wireless Communications Devices, " IEEE International Symposium on Electromagnetic Compatibility, Austin, TX, August, 1997.

5. Bronaugh, E. L., "Simplifying EMI Immunity (Susceptibility) Tests in TEM Cells," in the 1990 IEEE International Symposium on Electromagnetic Compatibility Symposium Record, Washington, D.C., August 1990, pp. 488-491

6. Byme, D. and Dillon, H., The National Acoustics Laboratory (NAL) New Procedure for Selecting the Gain and Frequency Response of a Hearing Aid, Ear and Hearing 7:257-265, 1986.

7. Crawford, M. L., "Measurement of Electromagnetic Radiation from Electronic Equipment using TEM Transmission Cells, " U.S. Department of Commerce, National Bureau of Standards, NBSIR 73-306, Feb. 1973.

8. Crawford, M. L., and Workman, J. L., "Using a TEM Cell for EMC Measurements of Electronic Equipment," U.S. Department of Commerce, National Bureau of Standards. Technical Note 1013, July 1981.

9. EHIMA GSM Project, Development phase, Project Report (1st part) Revision A. Technical-Audiological Laboratory and Telecom Denmark, October 1993.

10. EHIMA GSM Project, Development phase, Part II Project Report. Technical-Audiological Laboratory and Telecom Denmark, June 1994.

11. EHIMA GSM Project Final Report, Hearing Aids and GSM Mobile Telephones: Interference Problems, Methods of Measurement and Levels of Immunity. Technical-Audiological Laboratory and Telecom Denmark, 1995.

12. HAMPIS Report, Comparison of Mobile phone electromagnetic near field with an upscaled electromagnetic far field, using hearing aid as reference, 21 October 1999.

13. Hearing Aids/GSM, Report from OTWIDAM, Technical-Audiological Laboratory and Telecom Denmark, April 1993.

14. IEEE 100, The Authoritative Dictionary of IEEE Standards Terms, Seventh Edition.

15. Joyner, K. H, et. al., Interference to Hearing Aids by the New Digital Mobile Telephone System, Global System for Mobile (GSM) Communication Standard, National Acoustic Laboratory, Australian Hearing Series, Sydney 1993.

16. Joyner, K. H., et. al., Interference to Hearing Aids by the Digital Mobile Telephone System, Global System for Mobile Communications (GSM), NAL Report #131, National Acoustic Laboratory, Australian Hearing Series, Sydney, 1995.

17. Kecker, W. T., Crawford, M. L., and Wilson, W. A., "Contruction of a Transverse Electromagnetic Cell", U.S. Department of Commerce, National Bureau of Standards, Technical Note 1011, Nov. 1978.

18. Konigstein, D., and Hansen, D., "A New Family of TEM Cells with enlarged bandwidth and Optimized working Volume," in the Proceedings of the 7th International Symposium on EMC, Zurich, Switzerland, March 1987; 50:9, pp. 127-132.

19. Kuk, F., and Hjorstgaard, N. K., "Factors affecting interference from digital cellular telephones," Hearing Journal, 1997; 50:9, pp 32-34.

20. Ma, M. A., and Kanda, M., "Electromagnetic Compatibility and Interference Metrology," U.S. Department of Commerce, National Bureau of Standards, Technical Note 1099, July 1986, pp. 17-43.

21. Ma, M. A., Sreenivashiah, I. , and Chang, D. C., "A Method of Determining the Emission and Susceptibility Levels of Electrically Small Objects Using a TEM Cell," U.S. Department of Commerce, National Bureau of Standards, Technial Note 1040, July 1981.

22. McCandless, G. A., and Lyregaard, P. E., Prescription of Gain/Output (POGO) for Hearing Aids, Hearing Instruments 1:16-21, 1983

23. Skopec, M., "Hearing Aid Electromagnetic Interference from Digital Wireless Telephones, "IEEE Transactions on Rehabilitation Engineering, vol. 6, no. 2, pp. 235-239, June 1998.

24. Technical Report, GSM 05.90, GSM EMC Considerations, European Telecommunications Standards Institute, January 1993.

25. Victorian, T. A., "Digital Cellular Telephone Interference and Hearing Aid Compatibility—an Update," Hearing Journal 1998; 51:10, pp. 53-60

26. Wong, G. S. K., and Embleton, T. F. W., eds., AIP Handbook of Condenser Microphones: Theory, Calibration and Measurements, AIP Press.